



## 16Mx32 SDRAM

### FEATURES

- 40% Space Savings vs. Monolithic Solution
- Reduced System Inductance and Capacitance
- 3.3V Operating Supply Voltage
- Fully Synchronous to Positive Clock Edge
- Clock Frequencies of 100MHz - 133MHz
- Burst Operation
  - Sequential or Interleave
  - Burst Length = Programmable 1, 2, 4, 8 or Full Page
  - Burst Read and Write
  - Multiple Burst Read and Single Write
- Data Mask Control Per Byte
- Auto and Self Refresh
- Automatic and Controlled Precharge Commands
- Suspend Mode and Power Down Mode
- 119 Pin BGA, 17mm x 23mm

### DESCRIPTION

The WED3DL3216V is an 16Mx32 Synchronous DRAM configured as 4x4Mx32. The SDRAM BGA is constructed with two 16Mx16 SDRAM die mounted on a multi-layer laminate substrate and packaged in a 119 lead, 17mm by 23mm, BGA.

The WED3DL3216V is available in clock speeds of 133MHz, 125MHz, and 100MHz. The range of operating frequencies, programmable burst lengths and programmable latencies allow the same device to be useful for a variety of high bandwidth, high performance memory system applications.

The package and design provides performance enhancements via a 50% reduction in capacitance vs. two monolithic devices. The design includes internal ground and power planes which reduces inductance on the ground and power pins allowing for improved decoupling and a reduction in system noise.

### PIN CONFIGURATION (Top view)

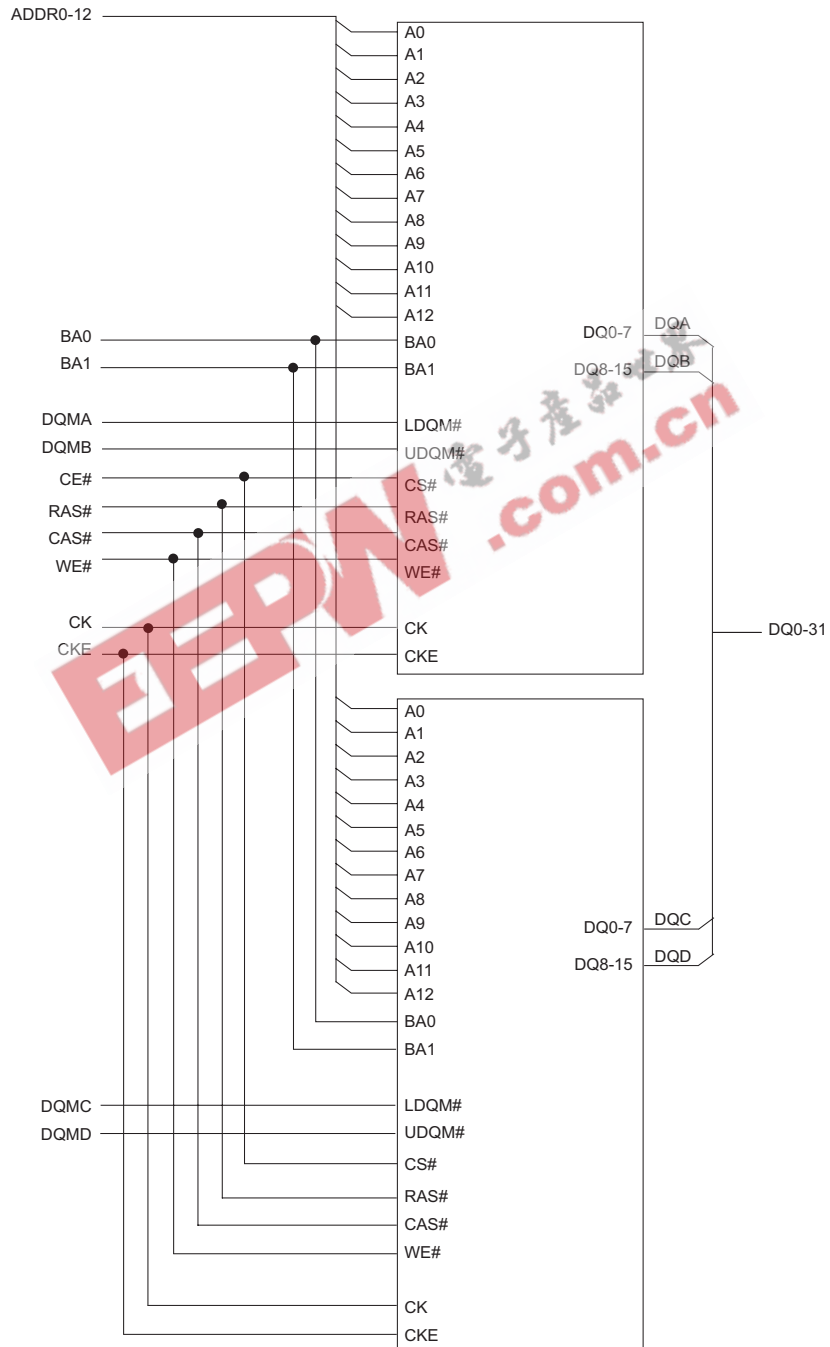
|   |                  |                 |                 |                 |                 |                 |                  |   |
|---|------------------|-----------------|-----------------|-----------------|-----------------|-----------------|------------------|---|
|   | 1                | 2               | 3               | 4               | 5               | 6               | 7                |   |
| A | V <sub>CCQ</sub> | NC              | BA0             | NC              | A10             | A7              | V <sub>CCQ</sub> | A |
| B | NC               | NC              | A12             | CAS#            | A11             | NC              | NC               | B |
| C | NC               | NC              | BA1             | V <sub>CC</sub> | A9              | A8              | NC               | C |
| D | DQC              | NC              | V <sub>SS</sub> | NC              | V <sub>SS</sub> | NC              | DQB              | D |
| E | DQC              | DQC             | V <sub>SS</sub> | CE#             | V <sub>SS</sub> | DQB             | DQB              | E |
| F | V <sub>CCQ</sub> | DQC             | V <sub>SS</sub> | RAS#            | V <sub>SS</sub> | DQB             | V <sub>CCQ</sub> | F |
| G | DQC              | DQC             | DQMC            | NC              | DQMB            | DQB             | DQB              | G |
| H | DQC              | DQC             | V <sub>SS</sub> | CKE             | V <sub>SS</sub> | DQB             | DQB              | H |
| J | V <sub>CCQ</sub> | V <sub>CC</sub> | NC              | V <sub>CC</sub> | NC              | V <sub>CC</sub> | V <sub>CCQ</sub> | J |
| K | DQD              | DQD             | V <sub>SS</sub> | CK              | V <sub>SS</sub> | DQA             | DQA              | K |
| L | DQD              | DQD             | DQMD            | NC              | DQMA            | DQA             | DQA              | L |
| M | V <sub>CCQ</sub> | DQD             | V <sub>SS</sub> | WE#             | V <sub>SS</sub> | DQA             | V <sub>CCQ</sub> | M |
| N | DQD              | DQD             | V <sub>SS</sub> | A1              | V <sub>SS</sub> | DQA             | DQA              | N |
| P | DQD              | NC              | V <sub>SS</sub> | A0              | V <sub>SS</sub> | NC              | DQA              | P |
| R | NC               | A6              | NC              | V <sub>CC</sub> | NC              | A2              | NC               | R |
| T | NC               | NC              | A5              | A4              | A3              | NC              | NC               | T |
| U | V <sub>CCQ</sub> | NC              | NC              | NC              | NC              | NC              | V <sub>CCQ</sub> | U |
|   | 1                | 2               | 3               | 4               | 5               | 6               | 7                |   |

### PIN DESCRIPTION

|                  |                                  |
|------------------|----------------------------------|
| A0 – A12         | Address Bus                      |
| BA0-1            | Bank Select Addresses            |
| DQ               | Data Bus                         |
| CK               | Clock                            |
| CKE              | Clock Enable                     |
| DQM              | Data Input/Output Mask           |
| RAS#             | Row Address Strobe               |
| CAS#             | Column Address Strobe            |
| CE#              | Chip Enable                      |
| V <sub>CC</sub>  | Power Supply pins, 3.3V          |
| V <sub>CCQ</sub> | Data Bus Power Supply pins, 3.3V |
| V <sub>SS</sub>  | Ground pins                      |



**16MX32 SDRAM BLOCK DIAGRAM**





**INPUT/OUTPUT FUNCTIONAL DESCRIPTION**

| Symbol          | Type         | Signal | Polarity      | Function  |
|-----------------|--------------|--------|---------------|---|
| CK              | Input        | Pulse  | Positive Edge | The system clock input. All of the SDRAM inputs are sampled on the rising edge of the clock   |
| CKE             | Input        | Level  | Active High   | Activates the CK signal when high and deactivates the CK signal when low. By deactivating the clock, CKE low initiates the Power Down mode, Suspend mode, or the Self Refresh mode  |
| CE#             | Input        | Pulse  | Active Low    | CE# disable or enable device operation by masking or enabling all inputs except CK, CKE and DQM.  |
| RAS#, CAS#, WE# | Input        | Pulse  | Active Low    | When sampled at the positive rising edge of the clock, CAS#, RAS# and WE# define the operation to be executed by the SDRAM  |
| BA0, BA1        | Input        | Level  | -             | Selects which SDRAM bank is to be active.   |
| A0-12           | Input        | Level  | -             | During a Bank Activate command cycle, A0-12 defines the row address (RA0-12) when sampled at the rising clock edge.   |
|                 |              |        |               | During a Read or Write command cycle, A0-9 defines the column address (CA0-9) when sampled at the rising edge of the clock. In addition to the row address, A10/AP is used to invoke Autoprecharge operation at the end of the Burst Read or Write cycle. If A10/AP is high, autoprecharge is selected and BA0, BA1 defines the bank to be precharged. If A10/AP is low, autoprecharge is disabled. |
|                 |              |        |               | During a Precharge command cycle, A10/AP is used in conjunction with BA0, BA1 to control which bank(s) to precharge. If A10/AP is high, all banks will be precharged regardless of the state of BA0, BA1. If A10/AP is low, then BA0, BA1 is used to define which bank to precharge.  |
| DQ              | Input/Output | Level  | -             | Data Input/Output are multiplexed on the same pins  |

**ABSOLUTE MAXIMUM RATINGS\***

| Parameter                    | Symbol                            | Min  | Max  | Units |
|------------------------------|-----------------------------------|------|------|-------|
| Power Supply Voltage         | V <sub>CC</sub> /V <sub>CCQ</sub> | -1.0 | +4.6 | V     |
| Input Voltage                | V <sub>IN</sub>                   | -1.0 | +4.6 | V     |
| Output Voltage               | V <sub>OUT</sub>                  | -1.0 | +4.6 | V     |
| Operating Temperature        | T <sub>OPR</sub>                  | -0   | +70  | °C    |
| Storage Temperature          | T <sub>TSG</sub>                  | -55  | +125 | °C    |
| Power Dissipation            | P <sub>D</sub>                    | —    | 1.5  | W     |
| Short Circuit Output Current | I <sub>OS</sub>                   | —    | 50   | mA    |

\* Stress greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions greater than those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



**RECOMMENDED DC OPERATING CONDITIONS**

(VOLTAGE REFERENCED TO:  $V_{SS} = 0V$ ,  $0^{\circ}C \leq T_A \leq 70^{\circ}C$ ; COMMERCIAL OR  $T_A = -40^{\circ}C$  TO  $+85^{\circ}C$ ; INDUSTRIAL)

| Parameter                                  | Symbol           | Min  | Typ | Max            | Unit    |
|--|------------------|------|-----|----------------|---------|
| Supply Voltage                             | $V_{CC}/V_{CCQ}$ | 3.0  | 3.3 | 3.6            | V       |
| Input High Voltage                         | $V_{IH}$         | 2.0  | 3.0 | $V_{CC} + 0.3$ | V       |
| Input Low Voltage                          | $V_{IL}$         | -0.3 | —   | 0.8            | V       |
| Output High Voltage<br>( $I_{OH} = -2mA$ ) | $V_{OH}$         | 2.4  | —   | —              | V       |
| Output Low Voltage<br>( $I_{OL} = 2mA$ )   | $V_{OL}$         | —    | —   | 0.4            | V       |
| Input Leakage Voltage                      | $I_{IL}$         | -5   | —   | 5              | $\mu A$ |
| Output Leakage Voltage                     | $I_{OL}$         | -5   | —   | 5              | $\mu A$ |

**CAPACITANCE**

( $T_A = 25^{\circ}C$ ,  $f = 1MHz$ ,  $V_{CC} = 3.3V$ )

| Parameter                     | Symbol    | Max | Unit |
|-------------------------------|-----------|-----|------|
| Input Capacitance             | $C_{I1}$  | 4   | pF   |
| Input/Output Capacitance (DQ) | $C_{OUT}$ | 5   | pF   |

**OPERATING CURRENT CHARACTERISTICS**

( $V_{CC} = 3.3V$ ,  $T_A = 0^{\circ}C$  TO  $70^{\circ}C$ ; COMMERCIAL OR  $T_A = -40^{\circ}C$  TO  $+85^{\circ}C$ ; INDUSTRIAL)

| Parameter   | Symbol      | Conditions   | -7  | -8  | -10 | Units |
|---|-------------|--|-----|-----|-----|-------|
| Operating Current (One Bank Active) <sup>1</sup>                | $I_{CC1}$   | Burst Length = 1, $t_{RC} \geq t_{RC}(min)$ , $I_{OL} = 0mA$         | 300 | 280 | 260 | mA    |
| Operating Current (Burst Mode) <sup>1</sup>                     | $I_{CC4}$   | Page Burst, 4 banks active, $t_{CCD} = 2$ clocks                     | 300 | 280 | 260 | mA    |
| Precharge Standby Current in Power Down Mode                    | $I_{CC2P}$  | $CKE \leq V_{IL}(max)$ , $t_{CC} = 15ns$                             | 2   | 2   | 2   | mA    |
|   | $I_{CC2PS}$ | $CKE, CK \leq V_{IL}(max)$ , $t_{CC} = \infty$ , Inputs Stable       | 2   | 2   | 2   | mA    |
| Precharge Standby Current in Non-Power Down Mode                | $I_{CC1N}$  | $CKE = V_{IH}$ , $t_{CC} = 15ns$<br>Input Change one time every 30ns | 140 | 140 | 140 | mA    |
|   | $I_{CC1NS}$ | $CKE \geq V_{IH}(min)$ , $t_{CC} = \infty$<br>No Input Change        | 70  | 70  | 70  | mA    |
| Precharge Standby Current in Power Down Mode                    | $I_{CC3P}$  | $CKE \leq V_{IL}(max)$ , $t_{CC} = 15ns$                             | 12  | 12  | 12  | mA    |
|   | $I_{CC3PS}$ | $CKE \leq V_{IL}(max)$ , $t_{CC} = \infty$                           | 12  | 12  | 12  | mA    |
| Active Standby Current in Non-Power Down Mode (One Bank Active) | $I_{CC3N}$  | $CKE = V_{IH}$ , $t_{CC} = 15ns$<br>Input Change one time every 30ns | 60  | 60  | 60  | mA    |
|   | $I_{CC3NS}$ | $CKE \geq V_{IH}(min)$ , $t_{CC} = \infty$ , No Input Change         | 50  | 50  | 50  | mA    |
| Refresh Current <sup>2</sup>                                    | $I_{CC5}$   | $t_{RC} \geq t_{RC}(min)$  | 600 | 570 | 550 | mA    |
| Self Refresh Current  | $I_{CC6}$   | $CKE \leq 0.2V$  | 6.5 | 6.5 | 6.5 | mA    |

**NOTES:**

1. Measured with outputs open.
2. Refresh period is 64ms.



**SDRAM AC CHARACTERISTICS**

| Parameter   | Symbol | 133MHz           |     | 125MHz |     | 100MHz |     | Units  |    |
|---|--------|------------------|-----|--------|-----|--------|-----|--------|----|
|   |        | Min              | Max | Min    | Max | Min    | Max |        |    |
|   | CL = 3 | t <sub>CC</sub>  | 7   | 1000   | 8   | 1000   | 10  | 1000   | ns |
|   | CL = 2 | t <sub>CC</sub>  | 7.5 | 1000   | 10  | 1000   | 12  | 1000   |    |
| Clock to valid Output delay <sup>1,2</sup>            |        | t <sub>SAC</sub> |     | 5.4    |     | 6      |     | 7      | ns |
| Output Data Hold Time <sup>2</sup>                    |        | t <sub>OH</sub>  | 3   |        | 3   |        | 3   |        | ns |
| Clock HIGH Pulse Width <sup>3</sup>                   |        | t <sub>CH</sub>  | 2.5 |        | 3   |        | 3   |        | ns |
| Clock LOW Pulse Width <sup>3</sup>                    |        | t <sub>CL</sub>  | 2.5 |        | 3   |        | 3   |        | ns |
| Input Setup Time <sup>3</sup>                         |        | t <sub>SS</sub>  | 1.5 |        | 2   |        | 2   |        | ns |
| Input Hold Time <sup>3</sup>                          |        | t <sub>SH</sub>  | 0.8 |        | 1   |        | 1   |        | ns |
| CK to Output Low-Z <sup>2</sup>                       |        | t <sub>SLZ</sub> | 2   |        | 2   |        | 2   |        | ns |
| CK to Output High-Z                                   |        | t <sub>SHZ</sub> |     | 5.4    |     | 6      |     | 7      | ns |
| Row Active to Row Active Delay <sup>4</sup>           |        | t <sub>RRD</sub> | 24  |        | 20  |        | 20  |        | ns |
| RAS to CAS Delay <sup>4</sup>                         |        | t <sub>RCD</sub> | 24  |        | 20  |        | 20  |        | ns |
| Row Precharge Time <sup>4</sup>                       |        | t <sub>RP</sub>  | 24  |        | 20  |        | 20  |        | ns |
| Row Active Time <sup>4</sup>                          |        | t <sub>RAS</sub> | 60  | 10,000 | 50  | 10,000 | 50  | 10,000 | ns |
| Row Cycle Time - Operation <sup>4</sup>               |        | t <sub>RC</sub>  | 90  |        | 70  |        | 80  |        | ns |
| Row Cycle Time - Auto Refresh <sup>4,8</sup>          |        | t <sub>RFC</sub> | 90  |        | 70  |        | 80  |        | ns |
| Last Data in to New Column Address Delay <sup>5</sup> |        | t <sub>CDL</sub> | 1   |        | 1   |        | 1   |        | CK |
| Last Data in to Row Precharge <sup>5</sup>            |        | t <sub>RDL</sub> | 1   |        | 1   |        | 1   |        | CK |
| Last Data in to Burst Stop <sup>5</sup>               |        | t <sub>BDL</sub> | 1   |        | 1   |        | 1   |        | CK |
| Column Address to Column Address Delay <sup>6</sup>   |        | t <sub>CCD</sub> | 1.5 |        | 1.5 |        | 1.5 |        | CK |
| Number of Valid OutputData <sup>7</sup>               |        |                  | 2   |        | 2   |        | 2   |        | ea |
|   |        |                  | 1   |        | 1   |        | 2   |        |    |

**NOTES:**

- Parameters depend on programmed CAS latency.
- If clock rise time is longer than 1ns (t<sub>RISE</sub>/2 - 0.5)ns should be added to the parameter.
- Assumed input rise and fall time = 1ns. If t<sub>RISE</sub> or t<sub>FALL</sub> are longer than 1ns. [(t<sub>RISE</sub> + t<sub>FALL</sub>)/2] - 1ns should be added to the parameter.
- The minimum number of clock cycles required is determined by dividing the minimum time required by the clock cycle time and then rounding up to the next higher integer.
- Minimum delay is required to complete write.
- All devices allow every cycle column address changes.
- In case of row precharge interrupt, auto precharge and read burst stop.



**COMMAND TRUTH TABLE**

| Function                        | CKE            |               | CE# | RAS# | CAS# | WE# | DQM | BA      | A0-A10      | A12, A11, | Notes |
|---------------------------------|----------------|---------------|-----|------|------|-----|-----|---------|-------------|-----------|-------|
|                                 | Previous Cycle | Current Cycle |     |      |      |     |     |         |             |           |       |
| Register Mode Register Set      | H              | X             | L   | L    | L    | L   | X   | OP CODE |             |           |       |
| Refresh Auto Refresh (CBR)      | H              | H             | L   | L    | L    | H   | X   | X       | X           | X         |       |
| Entry Self Refresh              | H              | L             | L   | L    | L    | H   | X   | X       | X           | X         |       |
| Precharge Single Bank Precharge | H              | X             | L   | L    | H    | L   | X   | BA      | L           | X         | 2     |
| Precharge all Banks             | H              | X             | L   | L    | H    | L   | X   | X       | H           | X         |       |
| Bank Activate                   | H              | X             | L   | L    | H    | H   | X   | BA      | Row Address |           | 2     |
| Write                           | H              | X             | L   | H    | L    | L   | X   | BA      | L           | Column    | 2     |
| Write with Auto Precharge       | H              | X             | L   | H    | L    | L   | X   | BA      | H           | Column    | 2     |
| Read                            | H              | X             | L   | H    | L    | L   | X   | BA      | L           | Column    | 2     |
| Read with Auto Precharge        | H              | X             | L   | H    | L    | H   | X   | BA      | H           | Column    | 2     |
| Burst Termination               | H              | X             | L   | H    | H    | L   | X   | X       | X           | X         | 3     |
| No Operation                    | H              | X             | L   | H    | H    | H   | X   | X       | X           | X         |       |
| Device Deselect                 | H              | X             | H   | X    | X    | X   | X   | X       | X           | X         |       |
| Clock Suspend/Standby Mode      | L              | X             | X   | X    | X    | X   | X   | X       | X           | X         | 4     |
| Data Write/Output Disable       | H              | X             | X   | X    | X    | X   | L   | X       | X           | X         | 5     |
| Data Mask/Output Disable        | H              | X             | X   | X    | X    | X   | H   | X       | X           | X         | 5     |
| Power Down Mode                 | Entry          | X             | L   | H    | X    | X   | X   | X       | X           | X         | 6     |
|                                 | Exit           | X             | H   | H    | X    | X   | X   | X       | X           | X         | 6     |

**NOTES:**

1. All of the SDRAM operations are defined by states of CE#, WE#, RAS#, CAS#, and DQM at the positive rising edge of the clock.
2. Bank Select (BA), if BA = 0 then bank A is selected, if BA = 1 then bank B is selected.
3. During a Burst Write cycle there is a zero clock delay, for a Burst Read cycle the delay is equal to the CAS latency.
4. During normal access mode, CKE is held high and CK is enabled. When it is low, it freezes the internal clock and extends data Read and Write operations. One clock delay is required for mode entry and exit.
5. The DQM has two functions for the data DQ Read and Write operations. During a Read cycle, when DQM goes high at a clock timing the data outputs are disabled and become high impedance after a two clock delay. DQM also provides a data mask function for Write cycles. When it activates, the Write operation at the clock is prohibited (zero clock latency).

All banks must be precharged before entering the Power Down Mode. The Power Down Mode does not perform any Refresh operations, therefore the device can't remain in this mode longer than the Refresh period (t<sub>REF</sub>) of the device. One clock delay is required for mode entry and exit.



**CLOCK ENABLE (CKE0) TRUTH TABLE**

| Current State                     | CKE            |               | Command |      |      |     |         |        | Action   | Notes |
|-----------------------------------|----------------|---------------|---------|------|------|-----|---------|--------|--|-------|
|                                   | Previous Cycle | Current Cycle | CE#     | RAS# | CAS# | WE# | BA0-1   | A10-11 |  |       |
| Self Refresh                      | H              | X             | X       | X    | X    | X   | X       | X      | INVALID  | 1     |
|                                   | L              | H             | H       | X    | X    | X   | X       | X      | Exit Self Refresh with Device Deselect                           | 2     |
|                                   | L              | H             | L       | H    | H    | H   | X       | X      | Exit Self Refresh with No Operation                              |       |
|                                   | L              | H             | L       | H    | H    | L   | X       | X      | ILLEGAL  |       |
|                                   | L              | H             | L       | H    | L    | X   | X       | X      | ILLEGAL  |       |
|                                   | L              | H             | L       | L    | X    | X   | X       | X      | ILLEGAL  |       |
| Power Down                        | L              | L             | X       | X    | X    | X   | X       | X      | Maintain Self Refresh  |       |
|                                   | H              | X             | X       | X    | X    | X   | X       | X      | INVALID  | 1     |
|                                   | L              | H             | H       | X    | X    | X   | X       | X      | Power Down Mode exit, all banks idle                             | 2     |
|                                   | L              | H             | L       | X    | X    | X   | X       | X      | ILLEGAL  | 2     |
| All Banks Idle                    | H              | X             | L       | H    | L    | L   | X       | X      | Maintain Power Down Mode   | 2     |
|                                   | H              | H             | H       | X    | X    | X   |         |        | Refer to the Idle State section of the Current State Truth Table | 3     |
|                                   | H              | H             | L       | H    | X    | X   |         |        |  |       |
|                                   | H              | H             | L       | L    | L    | H   | X       | X      | CBR Refresh  |       |
|                                   | H              | H             | L       | L    | L    | L   | OP Code |        | Mode Register Set  | 4     |
|                                   | H              | L             | H       | X    | X    | X   |         |        | Refer to the Idle State section of the Current State Truth Table | 3     |
|                                   | H              | L             | L       | H    | X    | X   |         |        |  |       |
|                                   | H              | L             | L       | L    | L    | H   | X       | X      | Entry Self Refresh   | 4     |
|                                   | H              | H             | L       | L    | L    | L   | OP Code |        | Mode Register Set  |       |
|                                   | L              | X             | X       | X    | X    | X   | X       | X      | Power Down   | 4     |
| Any State other than listed above | H              | H             | X       | X    | X    | X   | X       | X      | Refer to the Operations in the Current State Truth Table         |       |
|                                   | H              | L             | X       | X    | X    | X   | X       | X      | Begin Clock Suspend next cycle                                   | 5     |
|                                   | L              | H             | X       | X    | X    | X   | X       | X      | Exit Clock Suspend next cycle                                    |       |
|                                   | L              | L             | X       | X    | X    | X   | X       | X      | Maintain Clock Suspend   |       |

**NOTES:**

1. For the given Current State CKE must be low in the previous cycle.
2. When CKE has a low to high transition, the clock and other inputs are re-enabled asynchronously. The minimum setup time for CKE ( $t_{CKS}$ ) must be satisfied before any command other than Exit is issued.
3. The address inputs (A12-0) depend on the command that is issued. See the Idle State section of the Current State Truth Table for more information.
4. The Power Down Mode, Self Refresh Mode, and the Mode Register Set can only be entered from the all banks idle state.
5. Must be a legal command as defined in the Current State Truth Table.



CURRENT STATE TRUTH TABLE

| Current State            | Command |      |      |     |         |              | Action               | Notes                                    |     |
|--------------------------|---------|------|------|-----|---------|--------------|----------------------|--|-----|
|                          | CE#     | RAS# | CAS# | WE# | BA0-1   | A0-A12       | Description          |  |     |
| Idle                     | L       | L    | L    | L   | OP Code |              | Mode Register Set    | Set the Mode Register                    | 2   |
|                          | L       | L    | L    | H   | X       | X            | Auto or Self Refresh | Start Auto or Self Refresh               | 2,3 |
|                          | L       | L    | H    | L   | X       | X            | Precharge            | No Operation                             |     |
|                          | L       | L    | H    | H   | BA      | Row Address  | Bank Activate        | Activate the specified bank and row      |     |
|                          | L       | H    | L    | L   | BA      | Column       | Write w/o Precharge  | ILLEGAL                                  | 4   |
|                          | L       | H    | L    | H   | BA      | Column       | Read w/o Precharge   | ILLEGAL                                  |     |
|                          | L       | H    | H    | L   | X       | X            | Burst Termination    | No Operation                             | 2   |
|                          | L       | H    | H    | H   | X       | X            | No Operation         | No Operation                             |     |
| Row Active               | H       | X    | X    | X   | X       | X            | Device Deselect      | No Operation or Power Down               | 5   |
|                          | L       | L    | L    | L   | OP Code |              | Mode Register Set    | ILLEGAL                                  |     |
|                          | L       | L    | L    | H   | X       | X            | Auto or Self Refresh | ILLEGAL                                  |     |
|                          | L       | L    | H    | L   | X       | X            | Precharge            | Precharge                                | 6   |
|                          | L       | L    | H    | H   | BA      | Row Address  | Bank Activate        | ILLEGAL                                  | 2   |
|                          | L       | H    | L    | L   | BA      | Column       | Write                | Start Write; Determine if Auto Precharge | 7,8 |
|                          | L       | H    | L    | H   | BA      | Column       | Read                 | Start Read; Determine if Auto Precharge  |     |
|                          | L       | H    | H    | L   | X       | X            | Burst Termination    | No Operation                             |     |
| L                        | H       | H    | H    | X   | X       | No Operation | No Operation         |  |     |
| Read                     | H       | X    | X    | X   | X       | X            | Device Deselect      | No Operation                             |     |
|                          | L       | L    | L    | L   | OP Code |              | Mode Register Set    | ILLEGAL                                  |     |
|                          | L       | L    | L    | H   | X       | X            | Auto or Self Refresh | ILLEGAL                                  |     |
|                          | L       | L    | H    | L   | X       | X            | Precharge            | Terminate Burst; Start the Precharge     |     |
|                          | L       | L    | H    | H   | BA      | Row Address  | Bank Activate        | ILLEGAL                                  | 4   |
|                          | L       | H    | L    | L   | BA      | Column       | Write                | Terminate Burst; Start the Write cycle   | 8,9 |
|                          | L       | H    | L    | H   | BA      | Column       | Read                 | Terminate Burst; Start a new Read cycle  |     |
|                          | L       | H    | H    | L   | X       | X            | Burst Termination    | Terminate the Burst                      |     |
| L                        | H       | H    | H    | X   | X       | No Operation | Continue the Burst   |  |     |
| Write                    | H       | X    | X    | X   | X       | X            | Device Deselect      | Continue the Burst                       |     |
|                          | L       | L    | L    | L   | OP Code |              | Mode Register Set    | ILLEGAL                                  |     |
|                          | L       | L    | L    | H   | X       | X            | Auto or Self Refresh | ILLEGAL                                  |     |
|                          | L       | L    | H    | L   | X       | X            | Precharge            | Terminate Burst; Start the Precharge     |     |
|                          | L       | L    | H    | H   | BA      | Row Address  | Bank Activate        | ILLEGAL                                  | 4   |
|                          | L       | H    | L    | L   | BA      | Column       | Write                | Terminate Burst; Start a new Write cycle | 8,9 |
|                          | L       | H    | L    | H   | BA      | Column       | Read                 | Terminate Burst; Start the Read cycle    |     |
|                          | L       | H    | H    | L   | X       | X            | Burst Termination    | Terminate the Burst                      |     |
| L                        | H       | H    | H    | X   | X       | No Operation | Continue the Burst   |  |     |
| Read with Auto Precharge | H       | X    | X    | X   | X       | X            | Device Deselect      | Continue the Burst                       |     |
|                          | L       | L    | L    | L   | OP Code |              | Mode Register Set    | ILLEGAL                                  |     |
|                          | L       | L    | L    | H   | X       | X            | Auto or Self Refresh | ILLEGAL                                  |     |
|                          | L       | L    | H    | L   | X       | X            | Precharge            | ILLEGAL                                  | 4   |
|                          | L       | L    | H    | H   | BA      | Row Address  | Bank Activate        | ILLEGAL                                  |     |
|                          | L       | H    | L    | L   | BA      | Column       | Write                | ILLEGAL                                  |     |
|                          | L       | H    | L    | H   | BA      | Column       | Read                 | ILLEGAL                                  |     |
|                          | L       | H    | H    | L   | X       | X            | Burst Termination    | ILLEGAL                                  |     |
| L                        | H       | H    | H    | X   | X       | No Operation | Continue the Burst   |  |     |





CURRENT STATE TRUTH TABLE (cont.)

| Current State                       | Command |      |      |     |       |                 | Action                               | Notes                                    |      |
|-------------------------------------|---------|------|------|-----|-------|-----------------|--------------------------------------|--|------|
|                                     | CE#     | RAS# | CAS# | WE# | BA0-1 | A0-A12          | Description                          |  |      |
| Write with Auto Precharge           | L       | L    | L    | L   |       | OP Code         | Mode Register Set                    | ILLEGAL                                  |      |
|                                     | L       | L    | L    | H   | X     | X               | Auto orSelf Refresh                  | ILLEGAL                                  |      |
|                                     | L       | L    | H    | L   | X     | X               | Precharge                            | ILLEGAL                                  | 4    |
|                                     | L       | L    | H    | H   | BA    | Row Address     | Bank Activate                        | ILLEGAL                                  |      |
|                                     | L       | H    | L    | L   | BA    | Column          | Write                                | ILLEGAL                                  |      |
|                                     | L       | H    | L    | H   | BA    | Column          | Read                                 | ILLEGAL                                  |      |
|                                     | L       | H    | H    | L   | X     | X               | Burst Termination                    | ILLEGAL                                  |      |
|                                     | L       | H    | H    | H   | X     | X               | No Operation                         | Continue the Burst                       |      |
| L                                   | H       | X    | X    | X   | X     | Device Deselect | Continue the Burst                   |  |      |
| Precharging                         | L       | L    | L    | L   |       | OP Code         | Mode Register Set                    | ILLEGAL                                  |      |
|                                     | L       | L    | L    | H   | X     | X               | Auto orSelf Refresh                  | ILLEGAL                                  |      |
|                                     | L       | L    | H    | L   | X     | X               | Precharge                            | No Operation; Bank(s) idle after tRP     | 4    |
|                                     | L       | L    | H    | H   | BA    | Row Address     | Bank Activate                        | ILLEGAL                                  |      |
|                                     | L       | H    | L    | L   | BA    | Column          | Write w/o Precharge                  | ILLEGAL                                  |      |
|                                     | L       | H    | L    | H   | BA    | Column          | Read w/o Precharge                   | ILLEGAL                                  |      |
|                                     | L       | H    | H    | L   | X     | X               | Burst Termination                    | No Operation; Bank(s) idle after tRP     |      |
|                                     | L       | H    | H    | H   | X     | X               | No Operation                         | No Operation; Bank(s) idle after tRP     |      |
| H                                   | X       | X    | X    | X   | X     | Device Deselect | No Operation; Bank(s) idle after tRP |  |      |
| Row Activating                      | L       | L    | L    | L   |       | OP Code         | Mode Register Set                    | ILLEGAL                                  |      |
|                                     | L       | L    | L    | H   | X     | X               | Auto orSelf Refresh                  | ILLEGAL                                  |      |
|                                     | L       | L    | H    | L   | X     | X               | Precharge                            | ILLEGAL                                  | 4    |
|                                     | L       | L    | H    | H   | BA    | Row Address     | Bank Activate                        | ILLEGAL                                  | 4,10 |
|                                     | L       | H    | L    | L   | BA    | Column          | Write                                | ILLEGAL                                  | 4    |
|                                     | L       | H    | L    | H   | BA    | Column          | Read                                 | ILLEGAL                                  |      |
|                                     | L       | H    | H    | L   | X     | X               | Burst Termination                    | No Operation; Row active after tRCD      |      |
|                                     | L       | H    | H    | H   | X     | X               | No Operation                         | No Operation; Row active after tRCD      |      |
| H                                   | X       | X    | X    | X   | X     | Device Deselect | No Operation; Row active after tRCD  |  |      |
| Write Recovering                    | L       | L    | L    | L   |       | OP Code         | Mode Register Set                    | ILLEGAL                                  |      |
|                                     | L       | L    | L    | H   | X     | X               | Auto orSelf Refresh                  | ILLEGAL                                  |      |
|                                     | L       | L    | H    | L   | X     | X               | Precharge                            | ILLEGAL                                  | 4    |
|                                     | L       | L    | H    | H   | BA    | Row Address     | Bank Activate                        | ILLEGAL                                  |      |
|                                     | L       | H    | L    | L   | BA    | Column          | Write                                | Start Write; Determine if Auto Precharge | 9    |
|                                     | L       | H    | L    | H   | BA    | Column          | Read                                 | Start Read; Determine if Auto Precharge  |      |
|                                     | L       | H    | H    | L   | X     | X               | Burst Termination                    | No Operation; Row active after tDPL      |      |
|                                     | L       | H    | H    | H   | X     | X               | No Operation                         | No Operation; Row active after tDPL      |      |
| H                                   | X       | X    | X    | X   | X     | Device Deselect | No Operation; Row active after tDPL  |  |      |
| Write ecovering with Auto Precharge | L       | L    | L    | L   |       | OP Code         | Mode Register Set                    | ILLEGAL                                  |      |
|                                     | L       | L    | L    | H   | X     | X               | Auto orSelf Refresh                  | ILLEGAL                                  |      |
|                                     | L       | L    | H    | L   | X     | X               | Precharge                            | ILLEGAL                                  | 4    |
|                                     | L       | L    | H    | H   | BA    | Row Address     | Bank Activate                        | ILLEGAL                                  |      |
|                                     | L       | H    | L    | L   | BA    | Column          | Write                                | ILLEGAL                                  | 4,9  |
|                                     | L       | H    | L    | H   | BA    | Column          | Read                                 | ILLEGAL                                  |      |
|                                     | L       | H    | H    | L   | X     | X               | Burst Termination                    | No Operation; Precharge after tDPL       |      |
|                                     | L       | H    | H    | H   | X     | X               | No Operation                         | No Operation; Precharge after tDPL       |      |
| H                                   | X       | X    | X    | X   | X     | Device Deselect | No Operation; Precharge after tDPL   |  |      |



**CURRENT STATE TRUTH TABLE (cont.)**

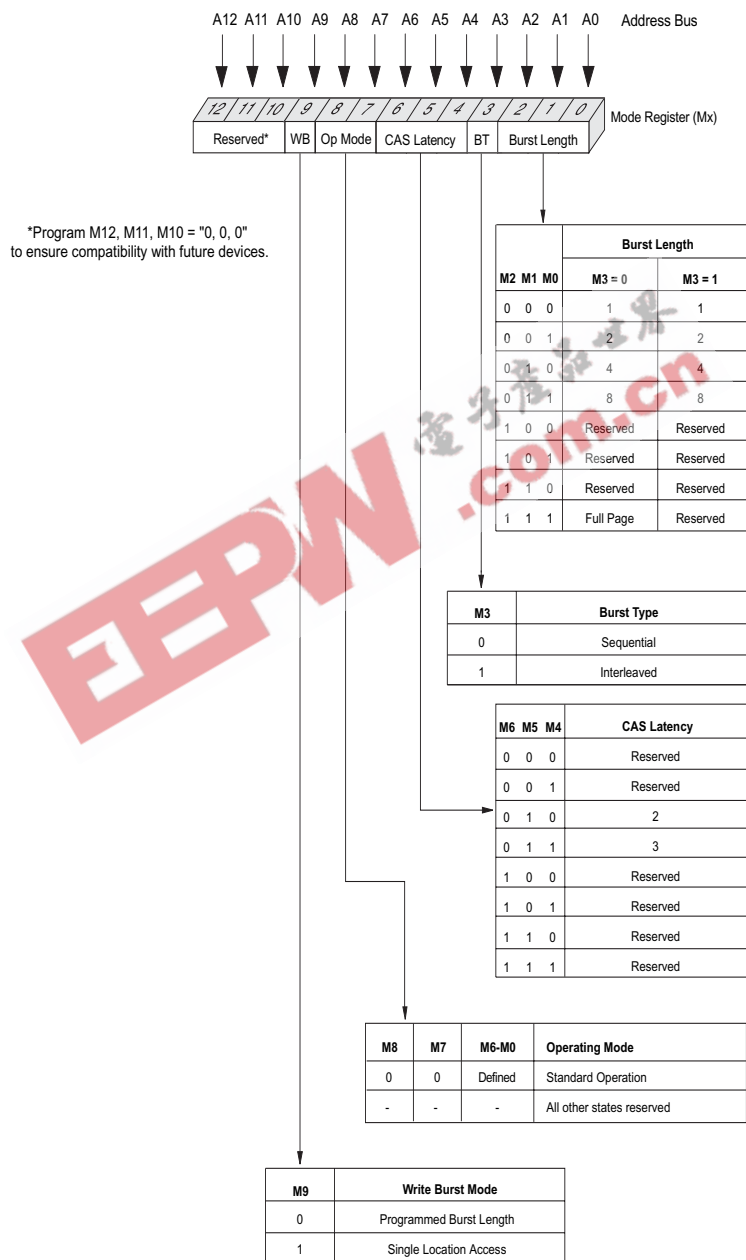
| Current State           | Command |      |      |     |         |             | Action               | Notes                                     |
|-------------------------|---------|------|------|-----|---------|-------------|----------------------|---|
|                         | CE#     | RAS# | CAS# | WE# | BA0-1   | A0-A12      | Description          |   |
| Refreshing              | L       | L    | L    | L   | OP Code |             | Mode Register Set    | ILLEGAL                                   |
|                         | L       | L    | L    | H   | X       | X           | Auto or Self Refresh | ILLEGAL                                   |
|                         | L       | L    | H    | L   | X       | X           | Precharge            | ILLEGAL                                   |
|                         | L       | L    | H    | H   | BA      | Row Address | Bank Activate        | ILLEGAL                                   |
|                         | L       | H    | L    | L   | BA      | Column      | Write                | ILLEGAL                                   |
|                         | L       | H    | L    | H   | BA      | Column      | Read                 | ILLEGAL                                   |
|                         | L       | H    | H    | L   | X       | X           | Burst Termination    | No Operation; Idle after t <sub>RC</sub>  |
|                         | L       | H    | H    | H   | X       | X           | No Operation         | No Operation; Idle after t <sub>RC</sub>  |
|                         | L       | H    | X    | X   | X       | X           | Device Deselect      | No Operation; Idle after t <sub>RC</sub>  |
| Mode Register Accessing | L       | L    | L    | L   | OP Code |             | Mode Register Set    | ILLEGAL                                   |
|                         | L       | L    | L    | H   | X       | X           | Auto or Self Refresh | ILLEGAL                                   |
|                         | L       | L    | H    | L   | X       | X           | Precharge            | ILLEGAL                                   |
|                         | L       | L    | H    | H   | BA      | Row Address | Bank Activate        | ILLEGAL                                   |
|                         | L       | H    | L    | L   | BA      | Column      | Write                | ILLEGAL                                   |
|                         | L       | H    | L    | H   | BA      | Column      | Read                 | ILLEGAL                                   |
|                         | L       | H    | H    | L   | X       | X           | Burst Termination    | ILLEGAL                                   |
|                         | L       | H    | H    | H   | X       | X           | No Operation         | No Operation; Idle after two clock cycles |
|                         | L       | H    | X    | X   | X       | X           | Device Deselect      | No Operation; Idle after two clock cycles |

**NOTES:**

1. CKE is assumed to be active (high) in the previous cycle for all entries. The Current State is the state of the bank that the command is being applied to.
2. Both Banks must be idle otherwise it is an illegal action.
3. If CKE is active (high) the SDRAM starts the Auto (CBR) Refresh operation, if CKE is inactive (low) then the Self Refresh mode is entered.
4. The Current State refers only refers to one of the banks, if BA selects this bank then the action is illegal. If BA selects the bank not being referenced by the Current State then the action may be legal depending on the state of that bank.
5. If CKE is inactive (low) than the Power Down mode is entered, otherwise there is a No Operation.
6. The minimum and maximum Active time (t<sub>RA</sub>) must be satisfied.
7. The RAS# to CAS# Delay (t<sub>RC</sub>) must occur before the command is given.
8. Address A10 is used to determine if the Auto Precharge function is activated.
9. The command must satisfy any bus contention, bus turn around, and/or write recovery requirements.
10. The command is illegal if the minimum bank to bank delay time (t<sub>RR</sub>) is not satisfied.

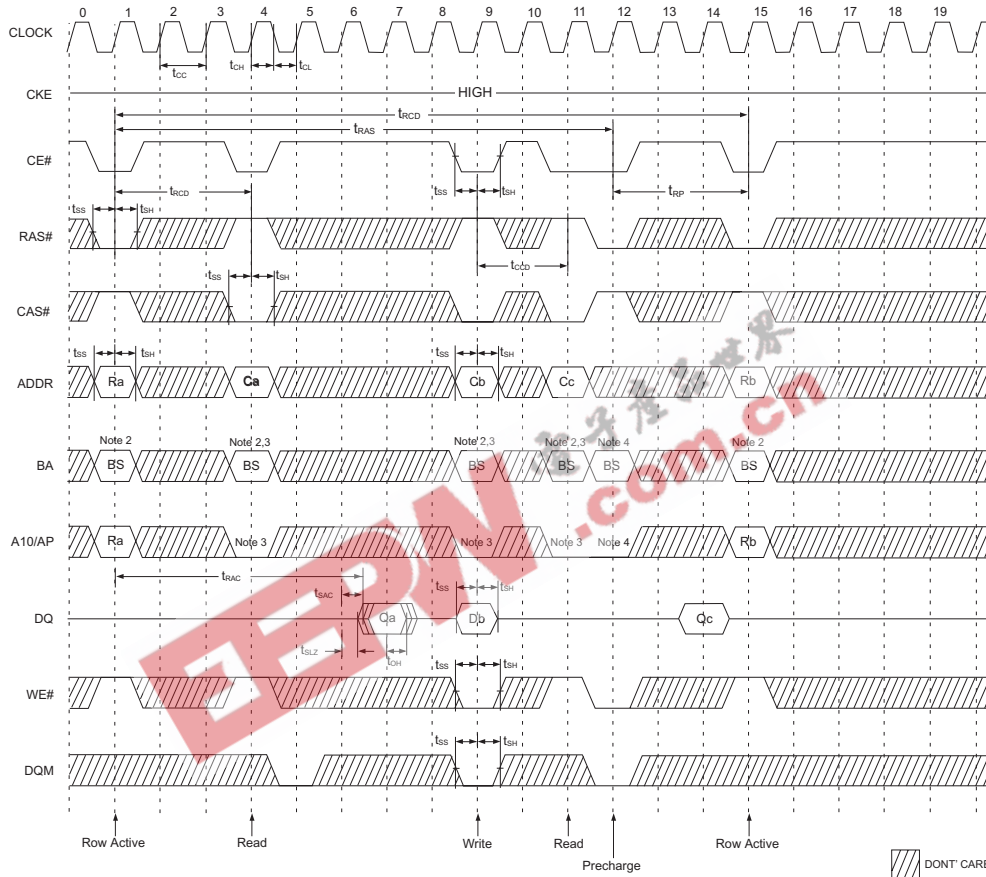


MODE REGISTER DEFINITION





**SINGLE BIT READ-WRITE CYCLE (SAME PAGE) @CAS LATENCY=3, BURST LENGTH=1**



**NOTES:**

- All input except CKE & DQM can be don't care when CE is high at the CK high going edge.
- Bank active & read/write are controlled by BA<sub>0</sub>-BA<sub>1</sub>.

| BA <sub>0</sub> | BA <sub>1</sub> | Active & Read/Write |
|-----------------|-----------------|---------------------|
| 0               | 0               | Bank A              |
| 0               | 1               | Bank B              |
| 1               | 0               | Bank C              |
| 1               | 1               | Bank D              |

- A10/AP and BA<sub>0</sub>-BA<sub>1</sub> control bank precharge when precharge command is asserted.

| A10/AP | BA <sub>0</sub> | BA <sub>1</sub> | Precharge |
|--------|-----------------|-----------------|-----------|
| 0      | 0               | 0               | Bank A    |
| 0      | 0               | 1               | Bank B    |
| 0      | 1               | 0               | Bank C    |
| 0      | 1               | 1               | Bank D    |
| 1      | x               | x               | All Banks |

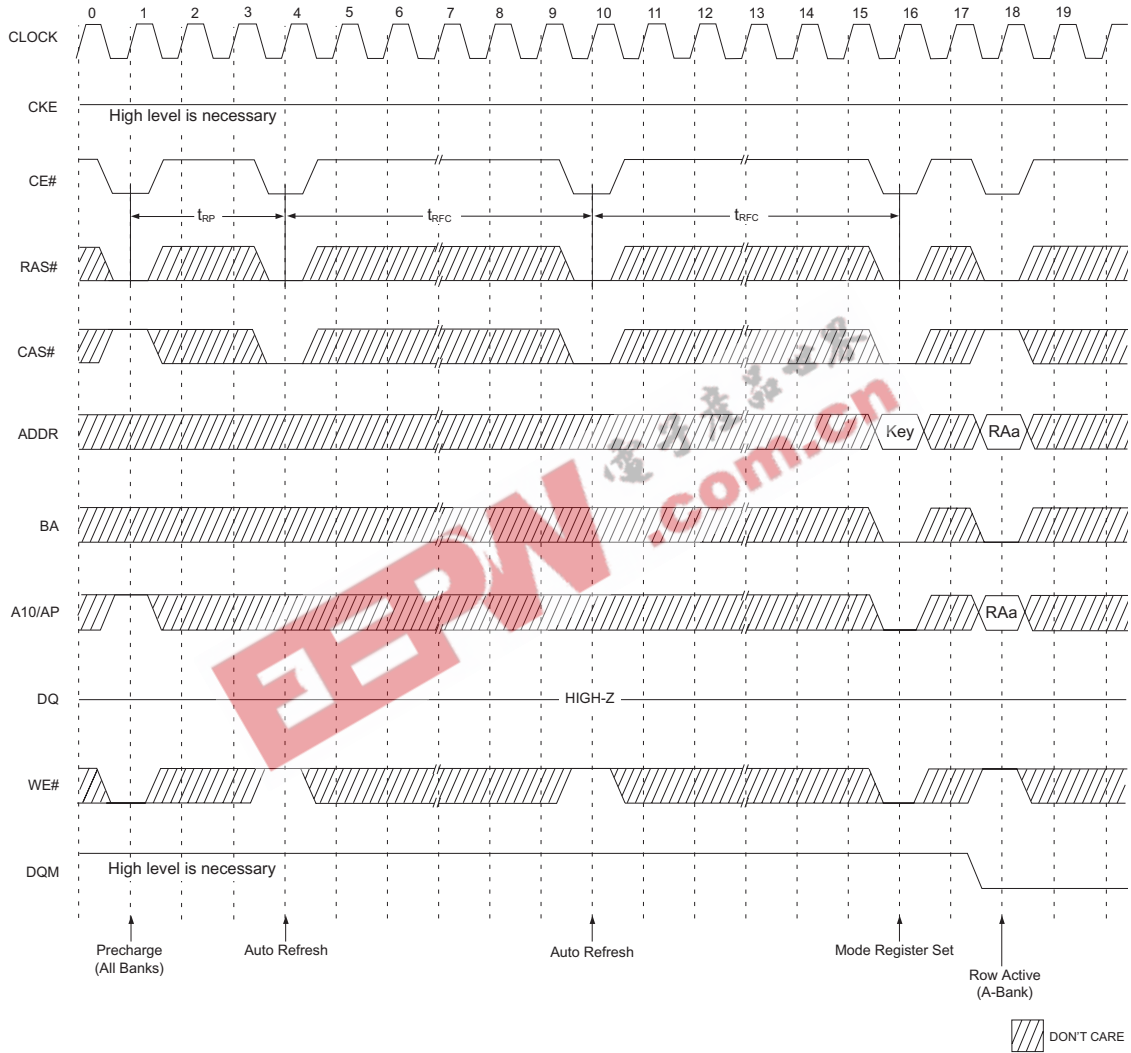
- Enable and disable auto precharge function are controlled by A10/AP in read/write command.

| A10/AP | BA <sub>0</sub> | BA <sub>1</sub> | Operation  |
|--------|-----------------|-----------------|--|
| 0      | 0               | 0               | Disable auto precharge, leave bank A active at end of burst. |
|        | 0               | 1               | Disable auto precharge, leave bank B active at end of burst. |
|        | 1               | 0               | Disable auto precharge, leave bank C active at end of burst. |
|        | 1               | 1               | Disable auto precharge, leave bank D active at end of burst. |
| 1      | 0               | 0               | Enable auto precharge, precharge bank A at end of burst.     |
|        | 0               | 1               | Enable auto precharge, precharge bank B at end of burst.     |
|        | 1               | 0               | Enable auto precharge, precharge bank C at end of burst.     |
|        | 1               | 1               | Enable auto precharge, precharge bank D at end of burst.     |

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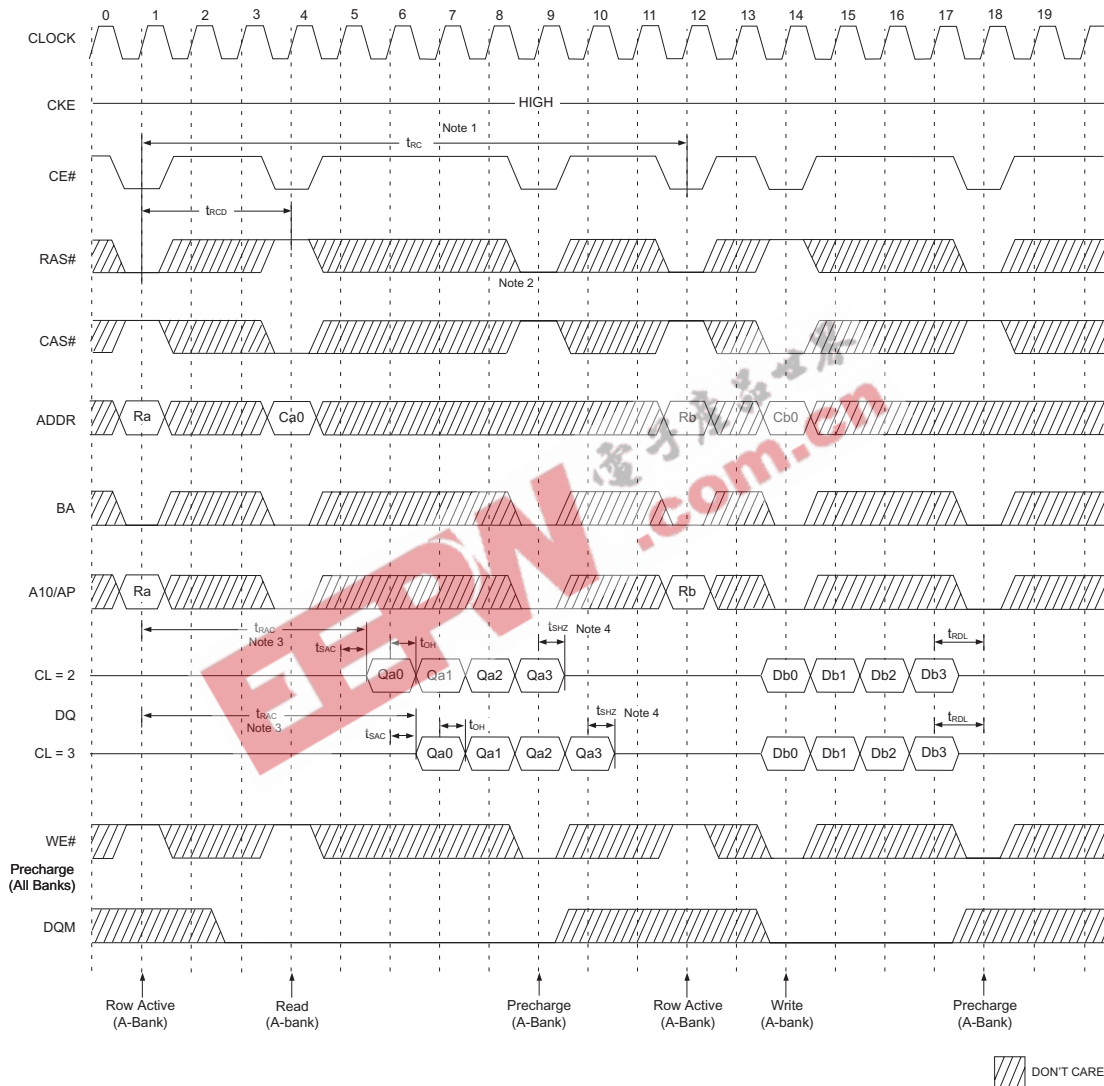


**POWER UP SEQUENCE**



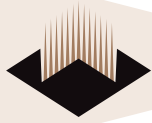


READ & WRITE CYCLE AT SAME BANK @ BURST LENGTH = 4

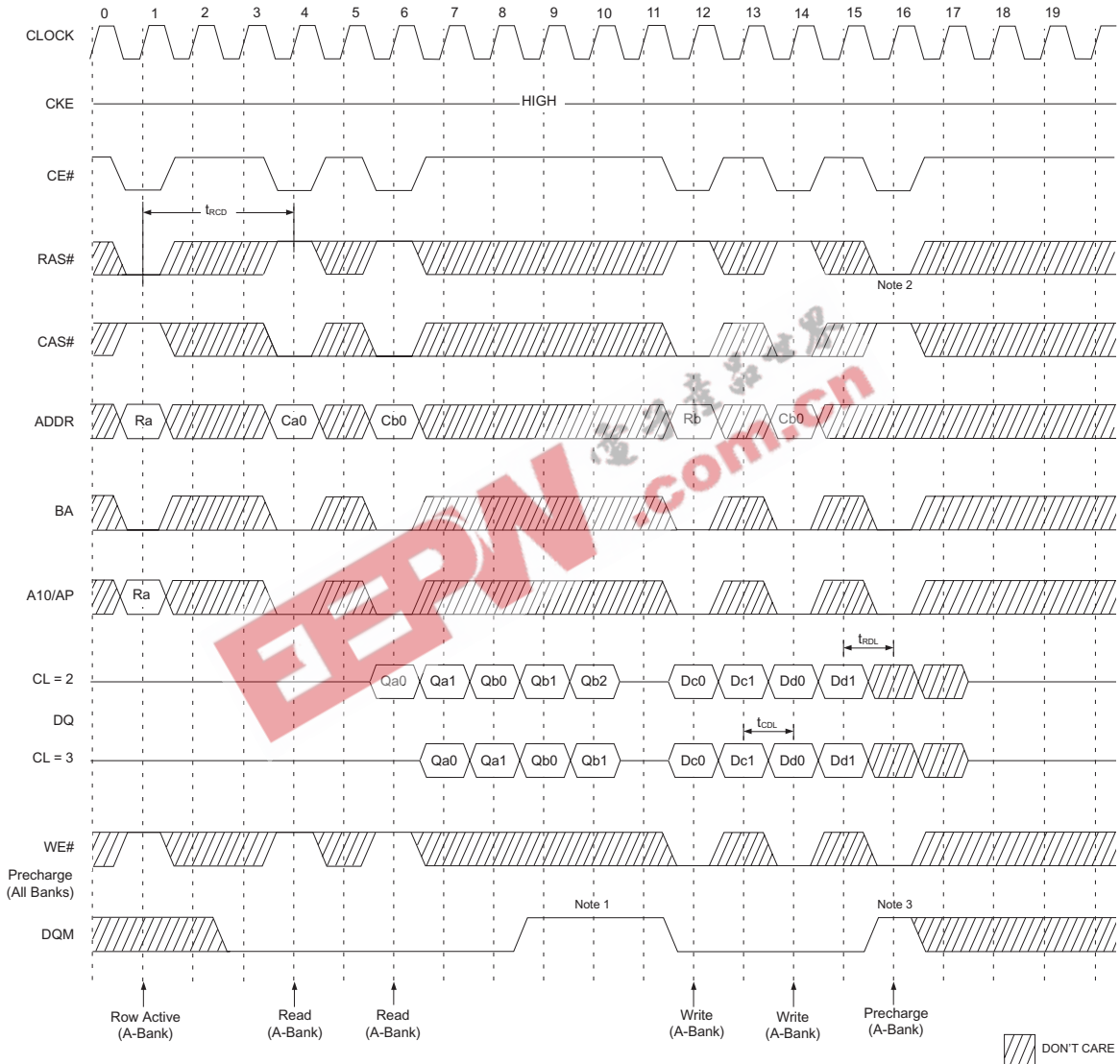


NOTES:

1. Minimum row cycle times are required to complete internal DRAM operation.
2. Row precharge can interrupt burst on any cycle. (CAS# Latency - 1) number of valid output data is available after Row precharge. Last valid output will be Hi-Z( $t_{SHZ}$ ) after the clock.
3. Access time from Row active command.  $t_{CC} * (t_{RCD} + CAS\# \text{ latency} - 1) + t_{CAC}$ .
4. Output will be Hi-Z after the end of burst (1, 2, 4, 8 & full page bit burst).

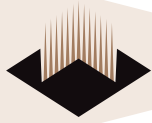


PAGE READ & WRITE CYCLE AT SAME BANK @ BURST LENGTH = 4

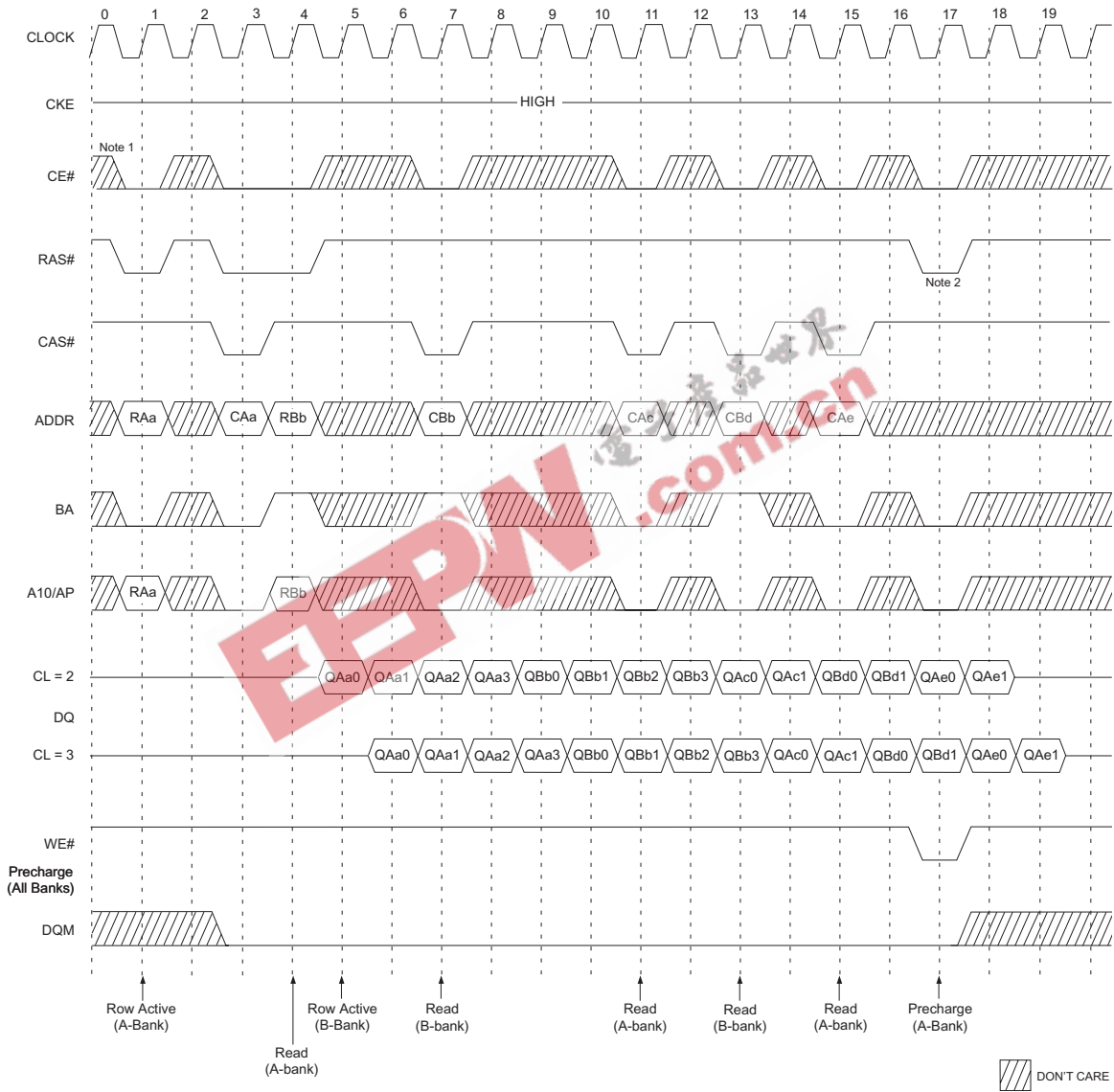


NOTES:

1. To write data before burst read ends, DQM should be asserted three cycles prior to write command to avoid bus contention.
2. Row precharge will interrupt writing. Last data input,  $t_{RDL}$  before Row precharge, will be written.
3. DQM should mask invalid input data on precharge command cycle when asserting precharge before end of burst. Input data after Row precharge cycle will be masked internally.



PAGE READ CYCLE AT DIFFERENT BANK @ BURST LENGTH = 4



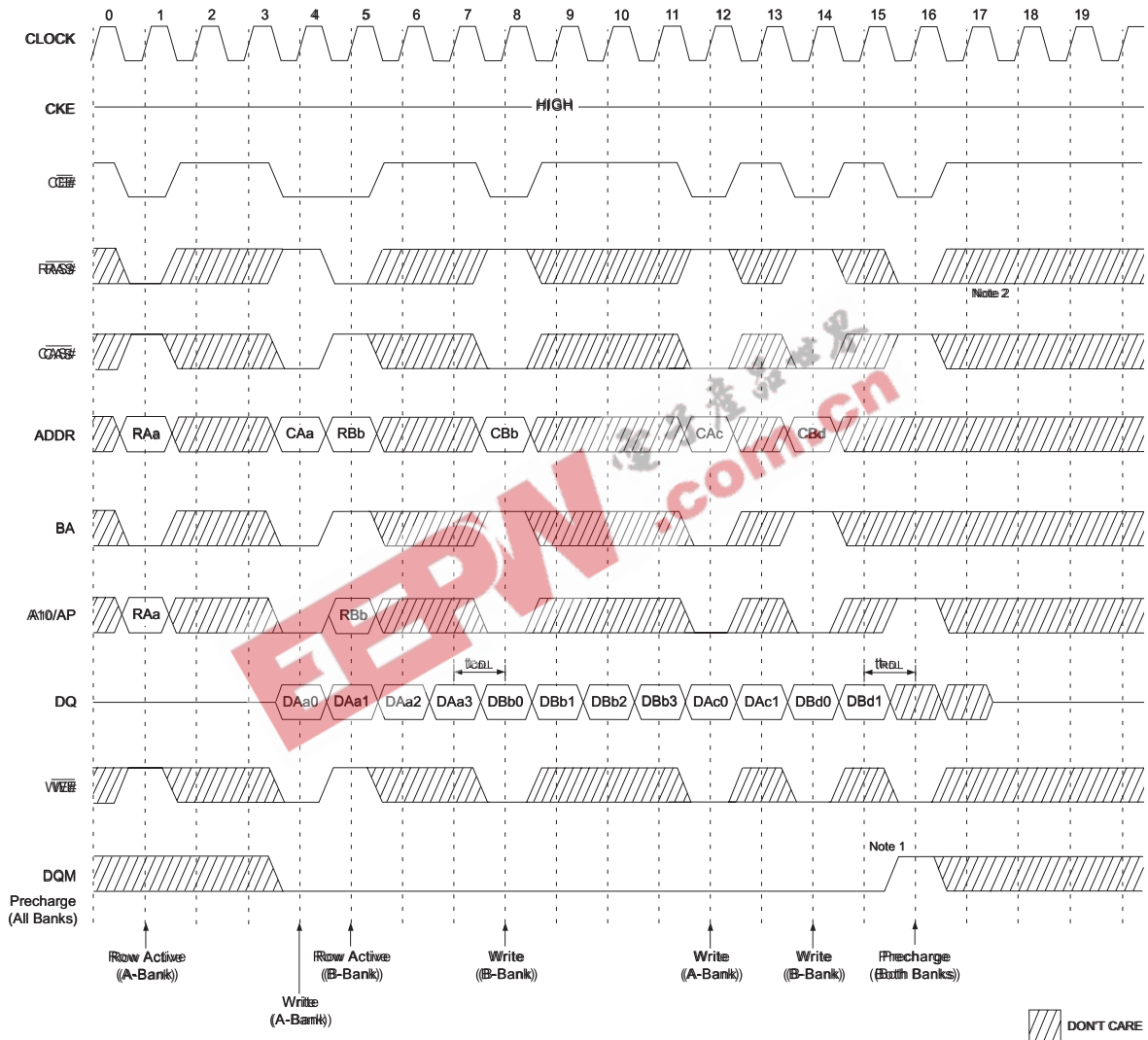
NOTES:

1. CE# can be don't cared when RAS#, CAS# and WE# are high at the clock high going edge.
2. To interrupt a burst read by row precharge, both the read and the precharge banks must be the same.



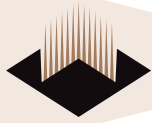


PAGE WRITE CYCLE AT DIFFERENT BANK @ BURST LENGTH = 4

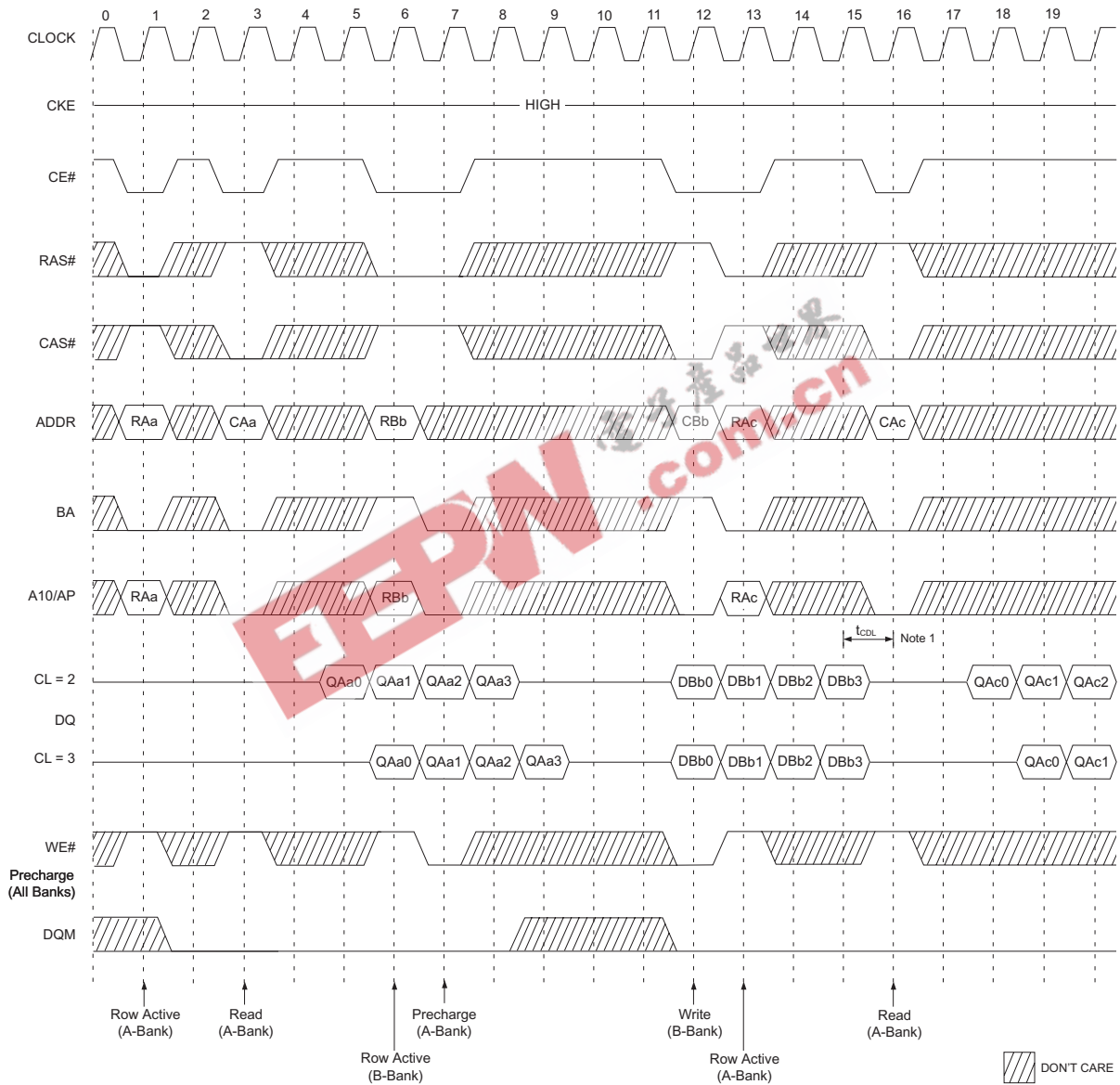


NOTES:

1. To interrupt burst write by Row precharge, DQM should be asserted to mask invalid input data.
2. To interrupt burst write by Row precharge, both the write and the precharge banks must be the same.



**READ & WRITE CYCLE AT DIFFERENT BANK @ BURST LENGTH = 4**

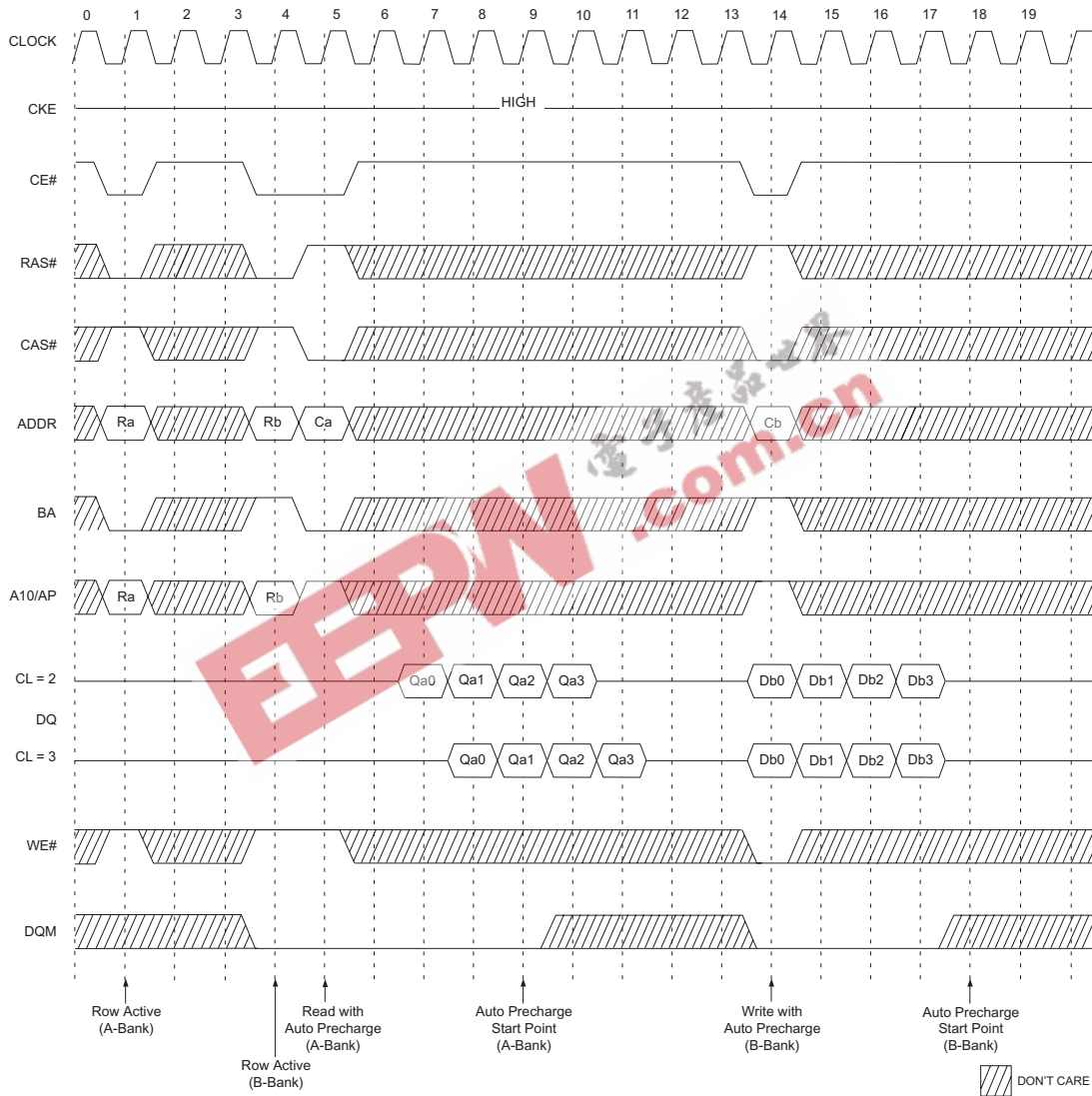


**NOTE:**

1.  $t_{CDL}$  should be met to complete write.



READ & WRITE CYCLE WITH AUTO PRECHARGE @ BURST LENGTH = 4

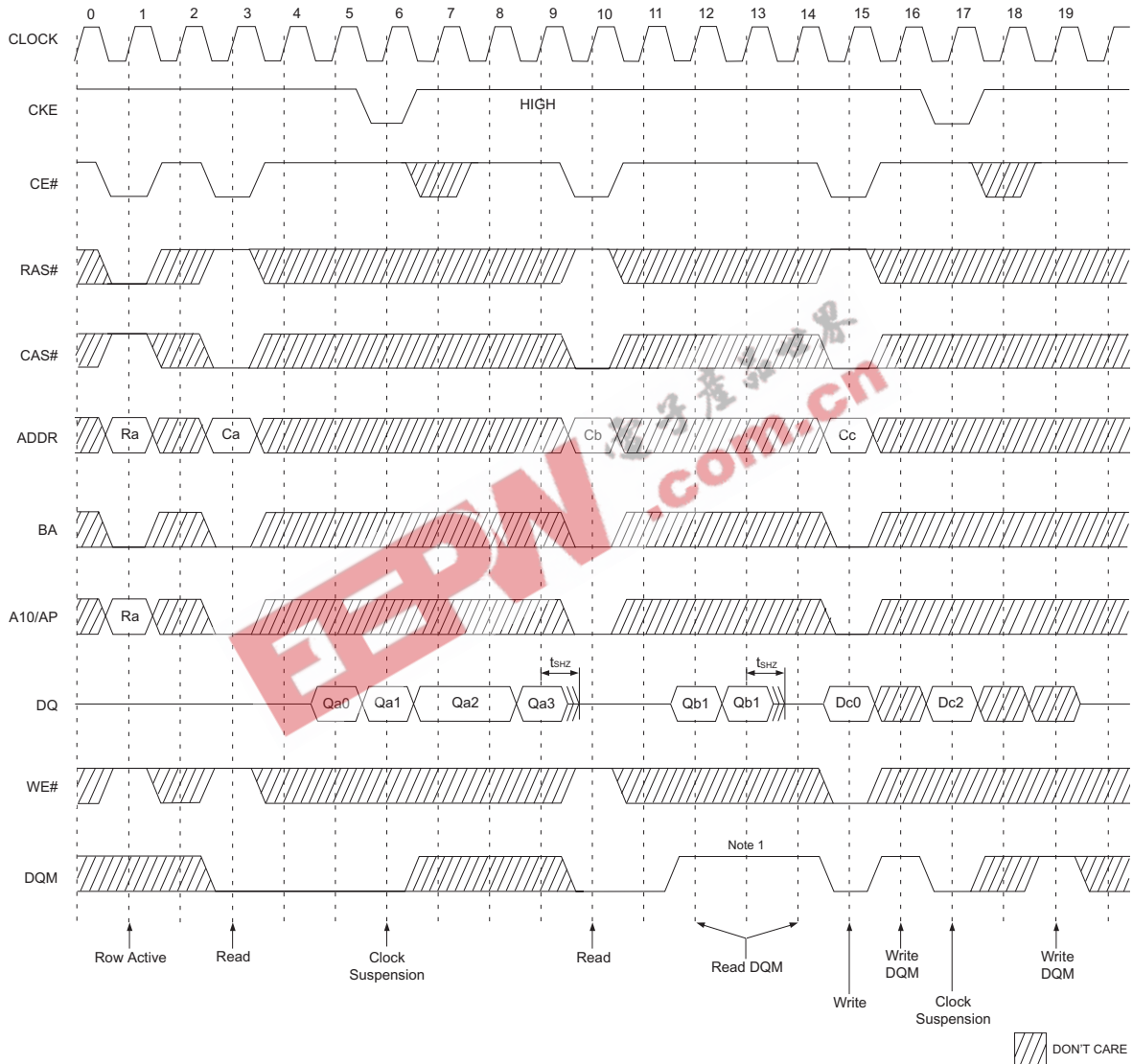


NOTE:

1.  $t_{CDL}$  should be controlled to meet minimum  $t_{RAS}$  before internal precharge start. (in the case of Burst Length = 1 & 2 and BRSW mode)



CLOCK SUSPENSION & DQM OPERATION CYCLE @ CAS LATENCY = 2, BURST LENGTH = 4

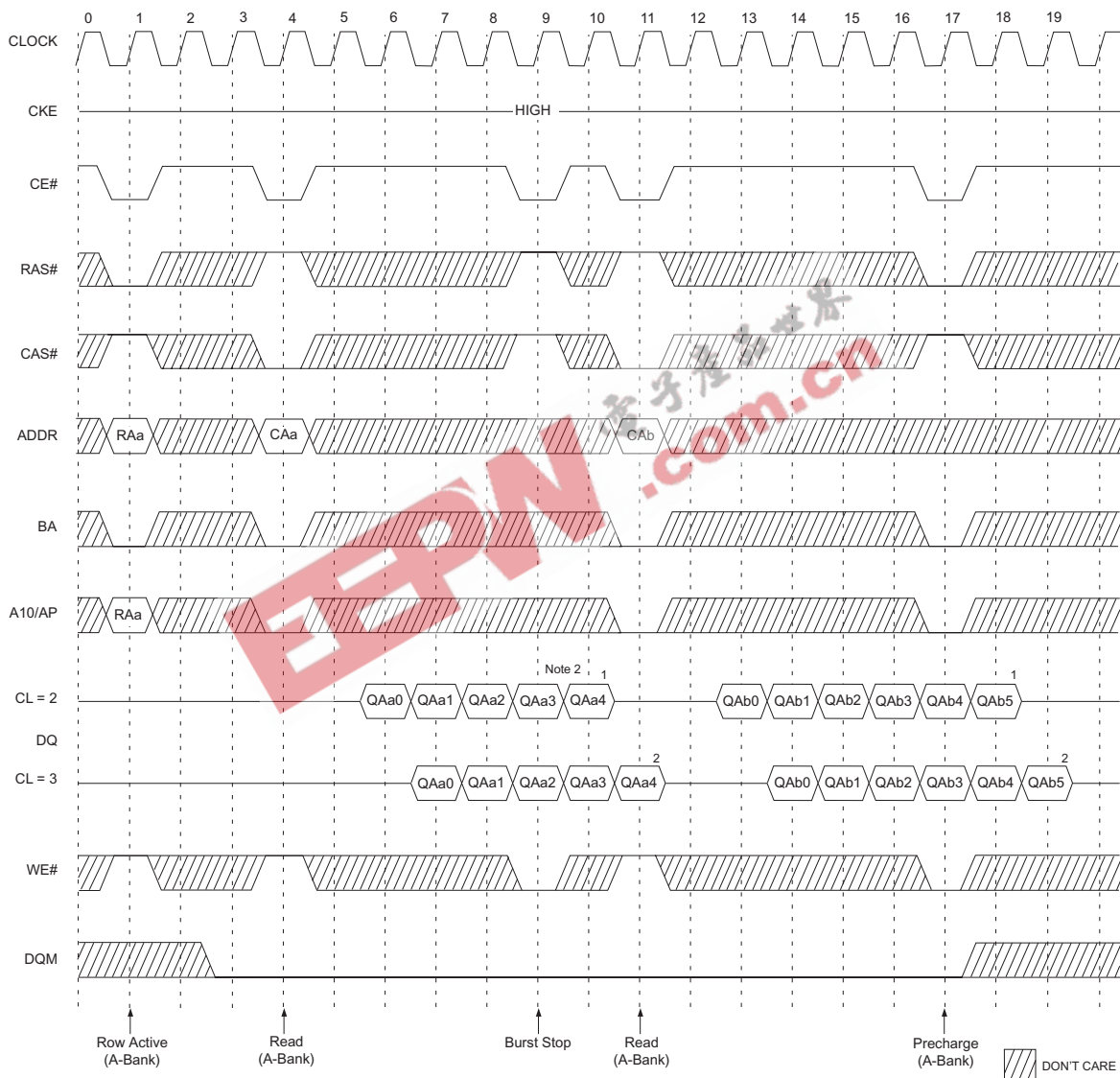


NOTE:

- 1. DQM is needed to prevent bus contention.



READ INTERRUPTED BY PRECHARGE COMMAND & READ BURST STOP @ BURST LENGTH = FULL PAGE

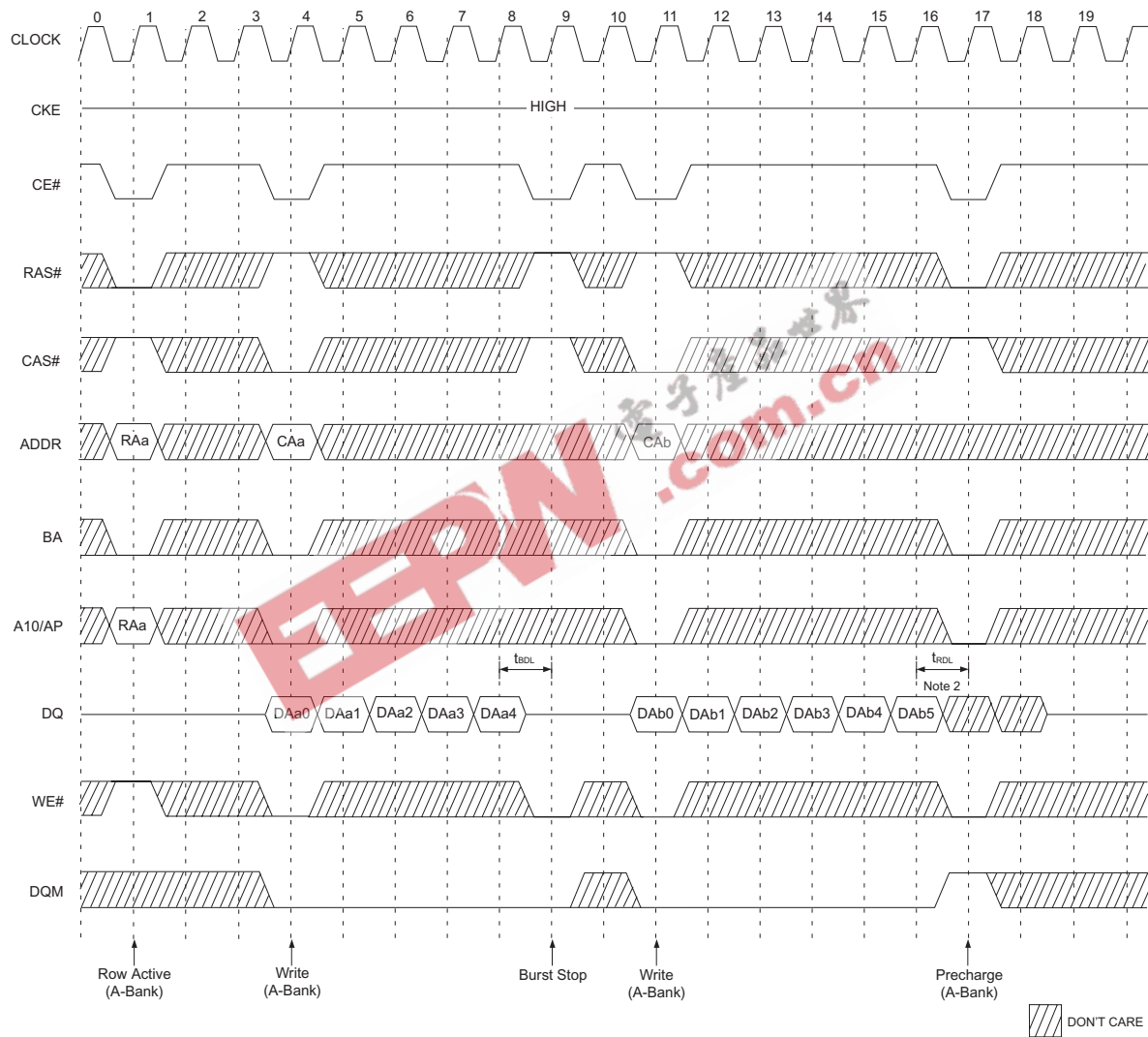


NOTES:

1. At full page mode, burst is end at the end of burst. So auto precharge is possible.
2. About the valid DQs after burst stop, it is same as the case of RAS# interrupt. Both cases are illustrated in above timing diagram. See the label 1, 2. But at burst write, Burst stop and RAS# interrupt should be compared carefully. Refer to the timing diagram of "Full page write burst stop cycle."
3. Burst stop is valid at every burst length.



WRITE INTERRUPTED BY PRECHARGE COMMAND & WRITE BURST STOP CYCLE @ BURST LENGTH = FULL PAGE

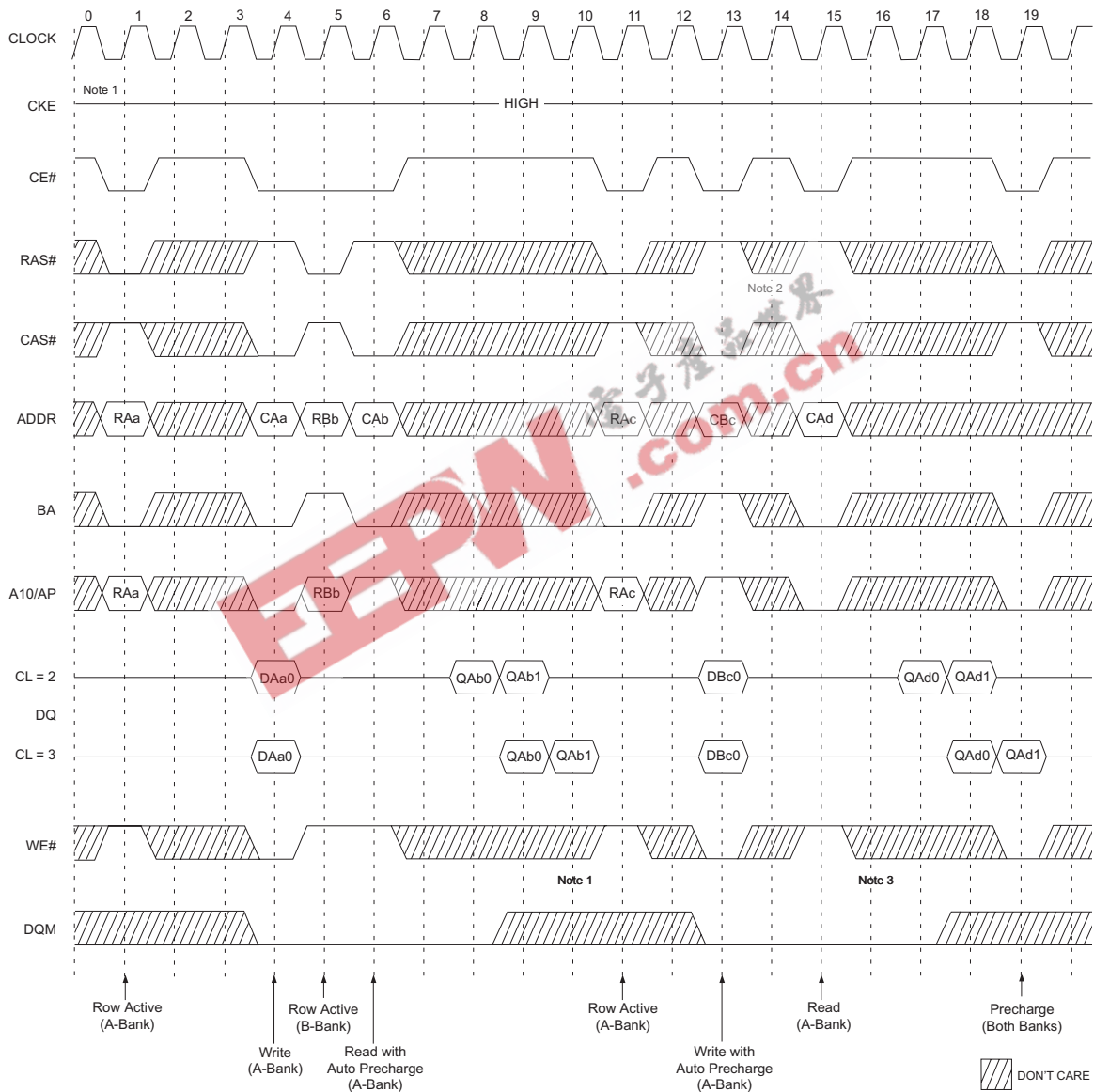


NOTES:

1. At full page mode, burst is end at the end of burst. So auto precharge is possible.
2. Data-in at the cycle of interrupted by precharge cannot be written into the corresponding memory cell. It is defined by AC parameter of  $t_{RD}$ . DQM at write interrupted by precharge command is needed to prevent invalid write. DQM should mask invalid input data on precharge command cycle when asserting precharge before end of burst. Input data after Row precharge cycle will be masked internally.
3. Burst stop is valid at every burst length.



**BURST READ SINGLE BIT WRITE CYCLE @ BURST LENGTH = 2  
@ BURST LENGTH = FULL PAGE**

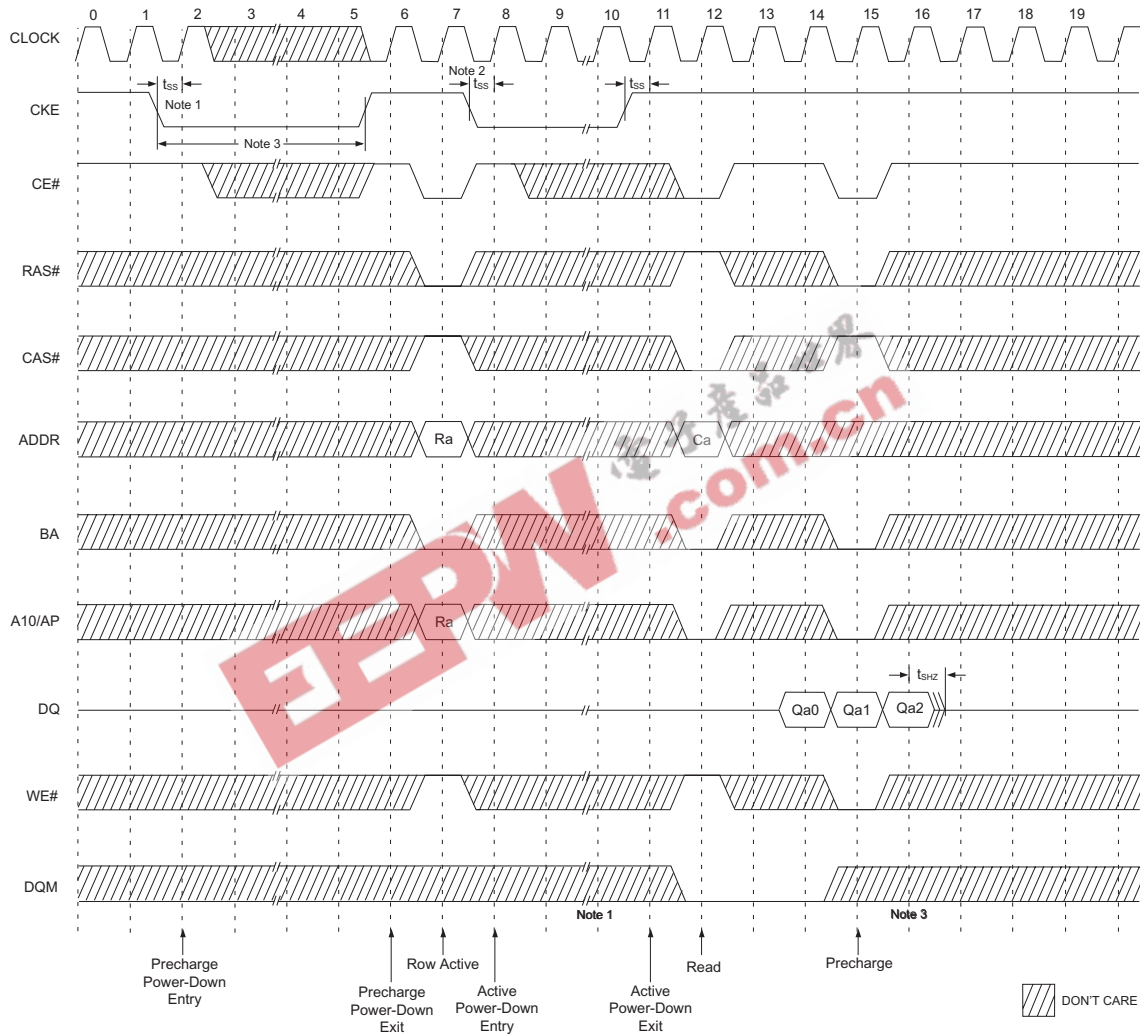


**NOTES:**

1. BRSW mode is enabled by setting As "High" at MRS (Mode Register Set). At the BRSW Mode, the burst length at write is fixed to "1" regardless of programmed burst length.
2. When BRSW write command with auto precharge is executed, keep it in mind that  $t_{RAS}$  should not be violated. Auto precharge is executed at the burst-end cycle, so in the case of BRSW write command, the next cycle starts the precharge.



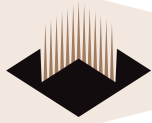
ACTIVE/PRECHARGE POWER DOWN MODE @ CAS LATENCY = 2, BURST LENGTH = 4



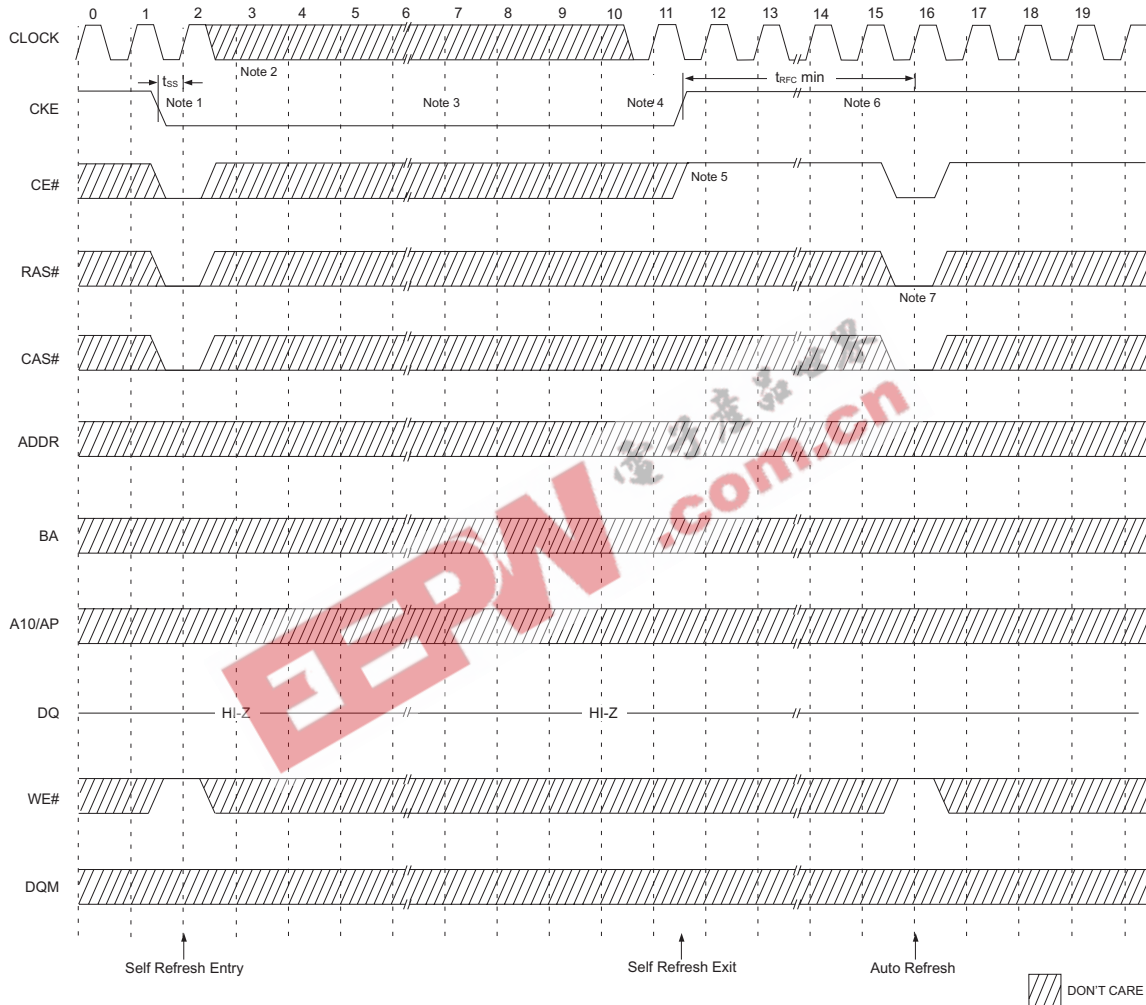
NOTES:

1. Both banks should be in idle state prior to entering precharge power down mode.
2. CKE should be set high at least  $1\text{ CK} + t_{ss}$  prior to Row active command.
3. Cannot violate minimum refresh specification (64ms).





SELF REFRESH ENTRY & EXIT CYCLE



NOTES:

TO ENTER SELF REFRESH MODE

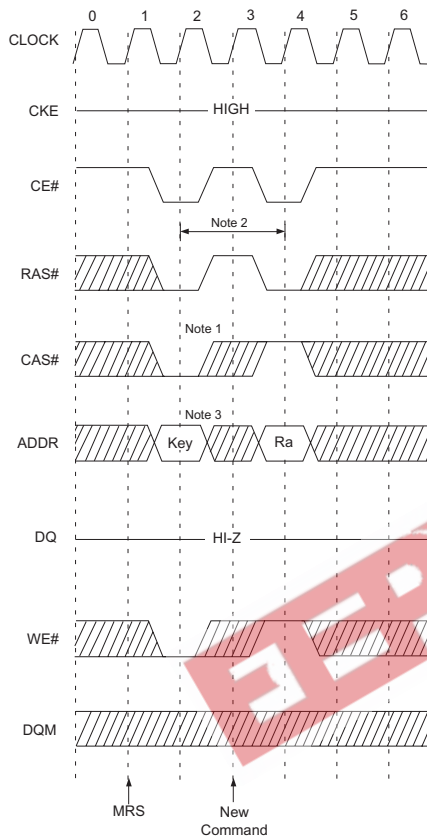
1. CE#, RAS# & CAS# with CKE should be low at the same clock cycle.
2. After 1 clock cycle, all the inputs including the system clock can be don't care except for CKE.
3. The device remains in self refresh mode as long as CKE stays "Low." Once the device enters self refresh mode, minimum  $t_{RAS}$  is required before exit from self refresh.

TO EXIT SELF REFRESH MODE

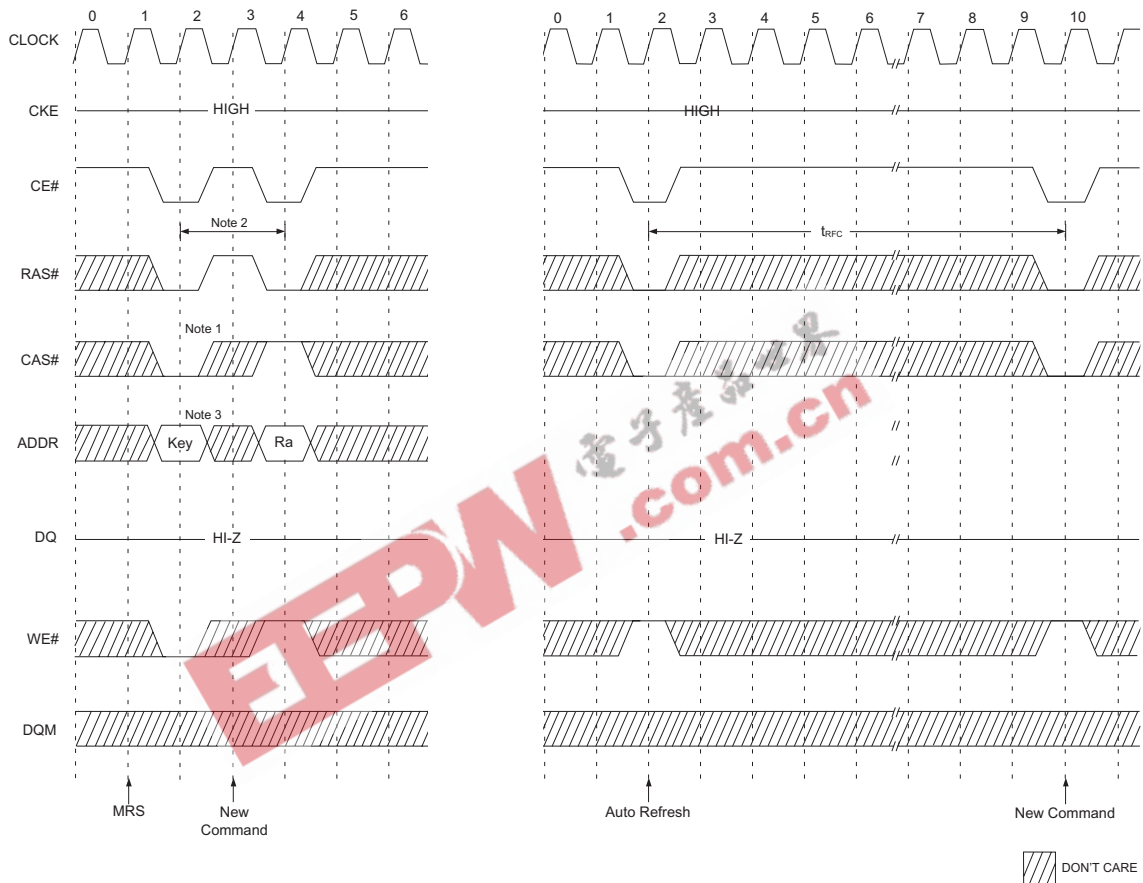
4. System clock restart and be stable before returning CKE high.
5. CE# starts from high.
6. Minimum  $t_{RFC}$  is required after CKE going high to complete self refresh exit.
7. 4K cycle of burst auto refresh is required before self refresh entry and after self refresh exit if the system uses burst refresh.



MODE REGISTER SET CYCLE



AUTO REFRESH CYCLE



NOTES:

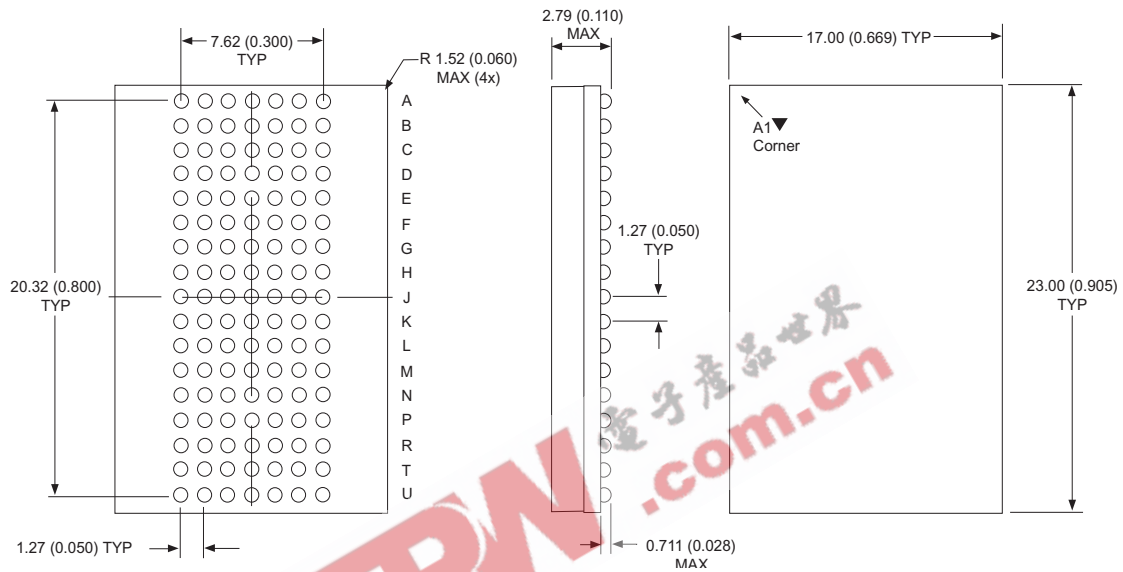
Both banks precharge should be completed before Mode Register Set cycle and auto refresh cycle.

MODE REGISTER SET CYCLE

1. CE#, RAS#, CAS#, & WE# activation at the same clock cycle with address key will set internal mode register.
2. Minimum 2 clock cycles should be met before new RAS# activation.
3. Please refer to Mode Register Set table.



**PACKAGE DESCRIPTION 119 PIN BGA  
JEDEC MO-163**



ALL DIMENSIONS ARE IN MILLIMETERS AND PARENTHETICALLY IN INCHES

**ORDERING INFORMATION**

| Part Number     | Clock Frequency              | Package |
|-----------------|------------------------------|---------|
| WED3DL3216V7BC  | 133MHz                       | 119 BGA |
| WED3DL3216V8BC  | 125MHz                       | 119 BGA |
| WED3DL3216V10BC | 100MHz                       | 119 BGA |
| WED3DL3216V7BI  | 133MHz, Industrial           | 119 BGA |
| WED3DL3216V8BI  | 125MHz, Industrial           | 119 BGA |
| WED3DL3216V10BI | 100MHz, Industrial           | 119 BGA |
| WED3DL3216V7ES  | 133MHz, Engineering Samples  | 119 BGA |
| WED3DL3216V10ES | 100 MHz, Engineering Samples | 119 BGA |